GW1NS series of FPGA Products

Datasheet

Revision History

Date	Version	Description
09/10/2018	1.0E	Initial version published (Preliminary).
11/22/2018	1.1E	GW1NS-2C added.
04/03/2019	1.2E	Operating conditions in Chapter 4 updated;
10/16/2019	1.3E	- VCCX of UX devices is greater than or equals to VCCIO. - GW1NS-4C/4 added. - BSRAM of GW1NS-4C/4 does not support Dual Port mode. - Description of Cortex-M3 updated.
11/12/2019	1.4E	- CS49 package info. added; - Max. I/O updated; - IODELAY description added.
03/18/2020	1.5E	- GW1NS-2 CS36U package info. added; - ADC reference voltage added; - GW1NS-LX2 VCCIO≤1.8V; - The description of CLKIN updated.
07/29/2020	1.6E	GW1NS-4/4C MG64 package info. added.
11/27/2020	1.6.1E	The Max. operating frequency of ARM Cortex-M3 updated.
11/11/2021	1.6.2E	The I/O standards and ordering information updated.
07/21/2022	1.6.3E	- Recommended I/O operating conditions updated. - The maximum value of the differential input threshold V_{THD} updated. - Note about USB 2.0 PHY added.
10/20/2022	1.7E	- Note about DC current limit added. - Architecture overviews of GW1NS series of FPGA products updated. - Table 3-5 POR Parameters updated. - GW1NS-2 and GW1NS-2C removed.
02/23/2023	1.7.1E	- Table 2-1 Output I/O Standards and Configuration Options updated. - Table 3-3 Power Supply Ramp Rates updated. - Table 3-8 DC Electrical Characteristics over Recommended Operating Conditions updated. - Section 3.4.4 Byte-enable removed. - Description of configuration Flash added. - Table 3-1 Absolute Max. Ratings updated. - Information on Slew Rate removed. - Table 3-24 GW1NS-4 User Flash Parameters[1], [4], [5] updated. - Description added to 2.5User Flash (GW1NS-4). - Description of true LVDS design modified.
05/25/2023	1.7.2E	2.4.2 Memory Configuration Modes added. - Information on User Flash of GW1NS-4C removed.
06/30/2023	1.8E	The I/O logic output diagram and the I/O logic input diagram combined into Figure 2-7 I/O Logic Input and

Date	Version	Description
		Output. • Note about the default state of GPIOs modified. • Description of MIPI input/output updated. • Table 3-3 Power Supply Ramp Rates updated. • GW1NS-4 QN32 added.
10/11/2023	1.9E	• Editorial updates. • Table 1-2 Device-Package Combinations, Maximum User I/Os, and (True LVDS Pairs) updated, correcting the maximum number of user IOs of the GW1NS-4C device in the MG64 package. • Section 2.4.6 Power up Conditions removed. • Note for Table 3-8 DC Electrical Characteristics over Recommended Operating Conditions modified. • Table 3-9 Static Current updated. • Table 3-16 Gearbox Timing Parameters optimized. • Table 3-24 GW1NS-4 User Flash Parameters[1], [4], [5] updated. • Figure 4-5 Package Marking Examples updated. • Note about the default state of GPIOs optimized.
05/09/2024	2.0E	• Description of IODELAY module updated. • Description of background upgrade added. • Description of HCLK optimized. • Note on Maximum GPIOs added to "Table 1-1 Product Resources". • Note added to "Table 3-2 Recommended Operating Conditions". • "Table 3-11 Single-ended I/O DC Characteristics" updated, modifying I_{OL} and I_{OH} of LVCMOS12 standard. • "Table 3-16 Gearbox Timing Parameters" updated.

Contents

List of Figures

List of Tables

1 General Description

The GW1NS series of FPGA products are the first generation products in the LittleBee family, including GW1NS-4C devices(embedded with an ARM Cortex-M3 processor) and GW1NS-4 devices.

The GW1NS-4C device is based on the ARM Cortex-M3 processor and has the minimum memory required to implement system functions. Its adaptable and flexible embedded FPGA logic modules enable the implementation of diverse peripheral control tasks, along with delivering excellent computing capabilities and advanced exception handling. Seamlessly integrating a programmable logic device with an embedded processor, the GW1NS-4C device is compatible with a range of peripheral standards, resulting in substantial cost savings for users. This makes it a highly versatile choice, suitable for a wide array of applications spanning industrial control, communications, IoT, servo drives, and consumer electronics, among others.

In addition, the GW1NS series FPGA products boast high performance, low power consumption, a small pin count, flexible usage, instant-on, low-cost, non-volatility, enhanced security, and a wide range of packaging options.

GOWINSEMI provides a new generation of FPGA hardware development environment that supports FPGA synthesis, placement & routing, bitstream generation and download, etc.

1.1 Features

- Lower power consumption
    - 55nm embedded flash technology
    - Core voltage: 1.2V
    - GW1NS-4C/4 support LV version only
    - Supports dynamically turning on/off the clock
- Hard core processor
    - Cortex-M3 32-bit RISC

- ARM3v7M architecture optimized for small-footprint embedded applications
- System timer (SysTick), providing a simple, 24-bit clear-on-write, decrementing, wrap-on-zero counter with a flexible control mechanism
- Thumb compatible, Thumb-2 instruction set processor core for high code density

- GW1NS-4C supports up to 80 MHz operation

- Hardware-division and single-cycle-multiplication

- Integrated nested vectored interrupt controller (NVIC) providing deterministic interrupt handling

- 26 interrupts with eight priority levels

- Memory protection unit (MPU), providing a privileged mode for protecting operation system functionality

- Unaligned data access, enabling data to be efficiently packed into memory

- Atomic bit manipulation (bit-banding), delivering maximum memory utilization and streamlined peripheral control

- Timer0 and Timer1

- UART0 and UART1

- watchdog

- Debug port: JTAG and TPIU

- User Flash (GW1NS-4)

  - NOR Flash

  - 256Kbits storage space

  - Data width:32bits

  - 10,000 write cycles

  - Greater than 10 years of data retention at +85℃

- Configuration Flash

  - NOR Flash

  - 10,000 write cycles

  - Greater than 10 years of data retention at +85℃

- Multiple I/O standards

  - LVCMOS33/25/18/15/12；LVTTL33，SSTL33/25/18 I，

SSTL33/25/18 II，SSTL15；HSTL18 I，HSTL18 II，HSTL15 I；PCI，LVDS25，RSDS，LVDS25E，BLVDSE，MLVDSE，LVPECLE，RSDSE

- Input hysteresis options

- Drive strength options

- Individual Bus Keeper, Pull-up/Pull-down, and Open Drain options

- Hot socketing

- GPIOs support MIPI D-PHY RX/TX

  - Bank0/Bank1 of GW1NS-4C/4 support MIPI input by using MIPI IO mode, and the MIPI data rate can be up to 1.2Gbps

  - Bank2 of GW1NS-4C/4 support MIPI output by using MIPI IO mode, and the MIPI data rate can be up to 1.2Gbps

  - Bank0/Bank1/Bank2 of GW1NS-4C/4 support I3C

- Abundant basic logic cells

  - 4-input LUTs (LUT4s)

  - Supports shift registers

- Block SRAMs with multiple modes

  - Supports Dual Port mode, Single Port mode, and Semi-Dual Port mode

- Flexible PLLs

  - Frequency adjustment (multiplication and division) and phase adjustment

  - Supports global clocks

- Built-in Flash programming

  - Instant-on

  - Supports security bit operation

  - Supports AUTO BOOT and DUAL BOOT

- Configuration

- JTAG configuration
- Multiple GowinCONFIG configuration modes: AUTO

BOOT, DUAL BOOT, SSPI, MSPI, CPU, SERIAL

1.2 Product Resources

Table 1-1 Product Resources

Device	GW1NS-4	GW1NS-4C
LUT4s	4,608	4,608
Flip-Flops (FFs)	3,456	3,456
Block SRAM(BSRAM) Capacity(bits)	180K	180K
Number of BSRAMs	10	10
Multiplier (18 x 18 Multiplier)	16	16
User Flash(bits)	256K	-
PLLs	2	2
OSC	1, ±5% tolerance	1, ±5% tolerance
Hard core processor	-	Cortex-M3
I/O Banks	4	4
Maximum GPIOs[1]	106	106
Core voltage	1.2V	1.2V

Note!

[1] This is the maximum number of GPIOs the device can provide without package limitation. Please refer to Table 1-2 for the maximum number of user I/Os available for the specific packages.

1.3 Package Information

Table 1-2 Device-Package Combinations, Maximum User I/Os, and (True LVDS Pairs)

Package	Pitch(mm)	Size(mm)	GW1NS-4C	GW1NS-4
CS49	0.4	2.9 x 2.9	42(8)	42(8)
MG64	0.5	4.2 x 4.2	55(8)	55(8)
QN32	0.5	5 x 5	-	23(1)
QN48	0.4	6 x 6	38(4)	38(4)

Note!

- JTAGSEL_N and JTAG pins cannot be used as GPIOs simultaneously. However, when mode [2:0] = 001, the JTAGSEL_N pin is always a GPIO, in other words the JTAGSEL_N pin and the four JTAG pins (TCK, TMS, TDI, TDO) can be used as GPIOs simultaneously. See UG823, GW1NS series of FPGA Products Package & Pinout User Guide for more information.

- The package types in this manual are referred to by acronyms, see 4.1 Part Naming for more information.

- See UG824, GW1NS-4&4C Pinout for more information.

2Architecture

2.1 Architecture Overview

Figure 2-1 Architecture Overview of GW1NS-4
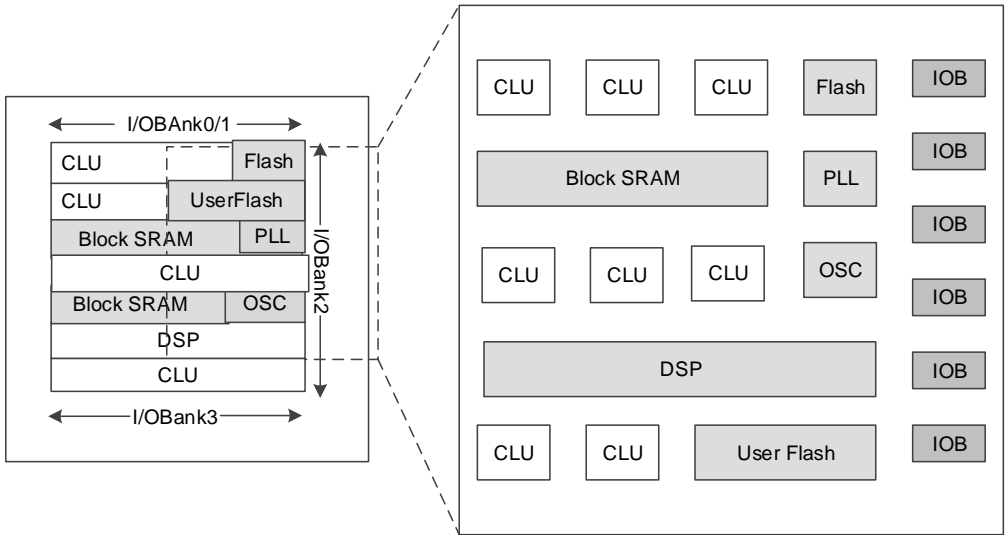
Figure 2-2 Architecture Overview of GW1NS-4C
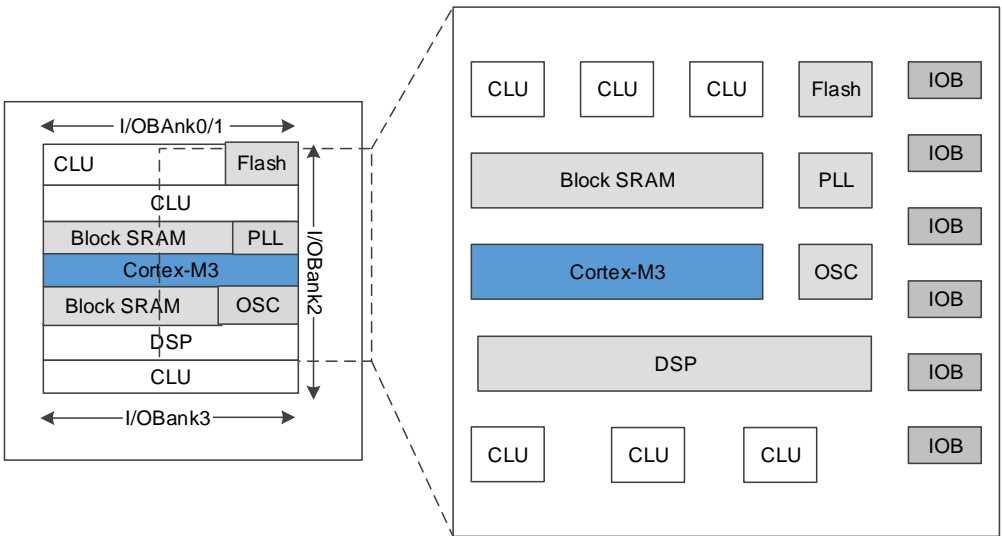
The core of the GW1NS device is an array of logic cells surrounded

by IO blocks. Besides, BSRAMs, DSP blocks, PLLs, an on-chip oscillator, and Flash resources allowing for instant-on are provided. See Table 1-1 for more information.

The Configurable Logic Units (CLUs) are the basic logic blocks that form the core of GW1NS FPGAs. Devices with different capacities have different numbers of rows and columns of CFUs/CLUs. For more information, see 2.2 Configurable Function Units.

The I/O resources in the GW1NS series of FPGA products are arranged around the periphery of the devices in groups referred to as banks. The I/O resources support multiple I/O standards and can be used for regular mode, SDR mode, and generic DDR mode. For more information, see 2.3 Input/Output Blocks.

BSRAMs are embedded as a row in the GW1NS series of FPGA products. Each BSRAM occupies 3 CLU locations. BSRAMs serve two main purposes. Firstly, they function as the SRAM resources for the Cortex-M3 processor system. The Gowin software supports the configuration of SRAM resources, offering options like 2K-Byte, 4K-Byte, and 8K-Byte. The capacity of a BSRAM when used as the SRAM for Cortex-M3 is 16Kbits (2K-Byte), and any unused BSRAMs are available for user storage. Secondly, BSRAMs can be utilized for user storage. In this case, the capacity of a BSRAM is up to 18Kbits and multiple configuration modes and operation modes are supported. For more information, see 2.4 Block SRAM.

GW1NS-4 has built-in User Flash memory resources, ensuring data retention even when powered off. See 2.5 User Flash (GW1NS-4) for more information.

GW1NS-4C and GW1NS-4 provide DSP blocks. DSP blocks are embedded as a row in the GW2A series of FPGA products. Each DSP block occupies 9 CLU locations. Each DSP block contains two macros, and each macro contains two pre-adders, two 18 x 18 bit multipliers, and one three-input ALU. For more information, see 2.6 Digital Signal Processing.

The GW1NS series of FPGA products have embedded PLL resources. The PLLs can provide synthesizable clock frequencies. Frequency adjustment (multiplication and division), phase adjustment, and duty cycle adjustment can be realized by configuring the parameters. These FPGAs have an embedded programmable on-chip clock oscillator that supports clock frequencies ranging from 2.5 MHz to 120MHz, providing clocking resources for the MSPI mode. It provides an MSPI clock source for the MSPI configuration mode with a tolerance of ±5%. For more information, see 2.8 Clocks.

The embedded configuration Flash resources in GW1NS FPGAs support instant-on and security bit operations, catering to AUTO BOOT and DUAL BOOT configuration modes.

The Cortex-M3 processor is embedded in GW1NS-4C. It supports 30 MHz program loading when the system starts up and supports higher speed data/instructions transmission. The AHB expansion bus facilitates

communication with external storage devices. The APB bus also facilitates communication with external devices, such as UART. GPIO interfaces are convenient for communicating with the external interfaces. The FPGA can be programmed to realize controller functions across different interfaces / standards, such as SPI, I²C, I3C, etc. For more information, see 2.7 Cortex-M3.

There are also abundant Configurable Routing Units (CRUs) that interconnect all the resources within the FPGA. For example, routing resources distributed in CLUs and IOBs interconnect resources in them. Routing resources can be automatically generated by the Gowin software. In addition, the GW1NS series of FPGA products also provide abundant dedicated clock resources, long wires (LWs), global set/reset (GSR) resources, programming options, etc. For more information, see 2.8 Clocks, 2.9 Long Wires, and 2.10 Global Set/Reset.

2.2 Configurable Function Units

Configurable Function Units (CFUs) and/or Configurable Logic Units (CLUs) are the basic cells for the core of GOWINSEMI FPGA Products. Each basic cell consists of four Configurable Logic Sections (CLSs) and their routing resource Configurable Routing Units (CRUs). Each of the three CLSs contains two 4-input LUTs and two registers, and the other one only contains two 4-input LUTs, as shown in Figure 2-3.

The CLSs in the CLUs cannot be configured as SRAMs, but can be configured as basic LUTs, ALUs, and ROMs. The CLSs in the CFUs can be configured as basic LUTs, ALUs, SRAMs, and ROMs according to application scenarios.

For more information, see UG288, Gowin Configurable Function Unit (CFU) User Guide.

Figure 2-3 CLU Structure View
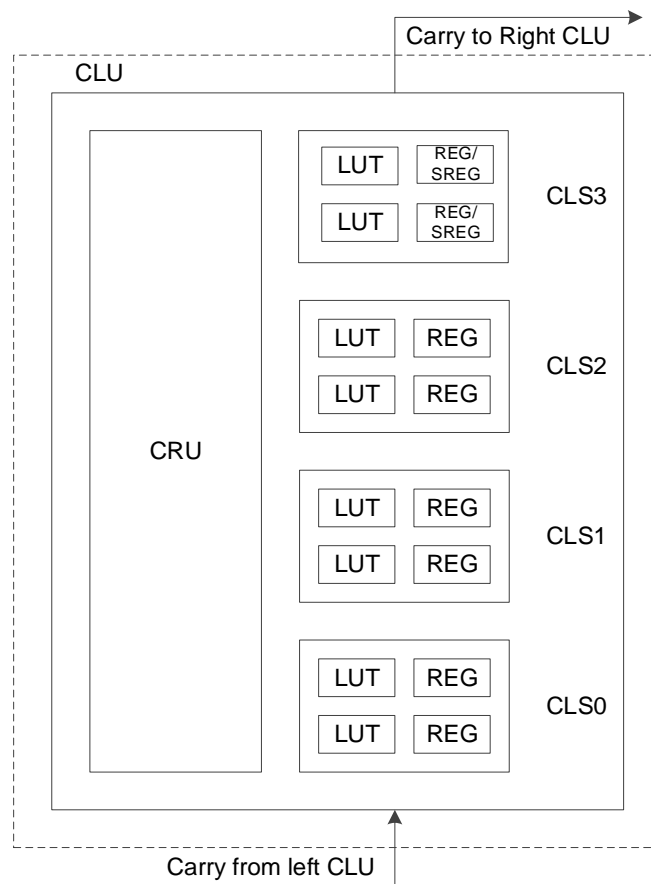
Note!

The SREGs need special patch support. Please contact Gowin's technical support or local office for this patch.

2.3 Input/Output Blocks

The Input/Output Block (IOB) in the GW1NS series of FPGA products consists a buffer pair, IO logic, and corresponding routing units. As shown in Figure 2-4, each IOB connects to two pins (marked as A and B), which can be used as a differential pair or as two single-ended inputs/outputs.

Figure 2-4 IOB Structure View
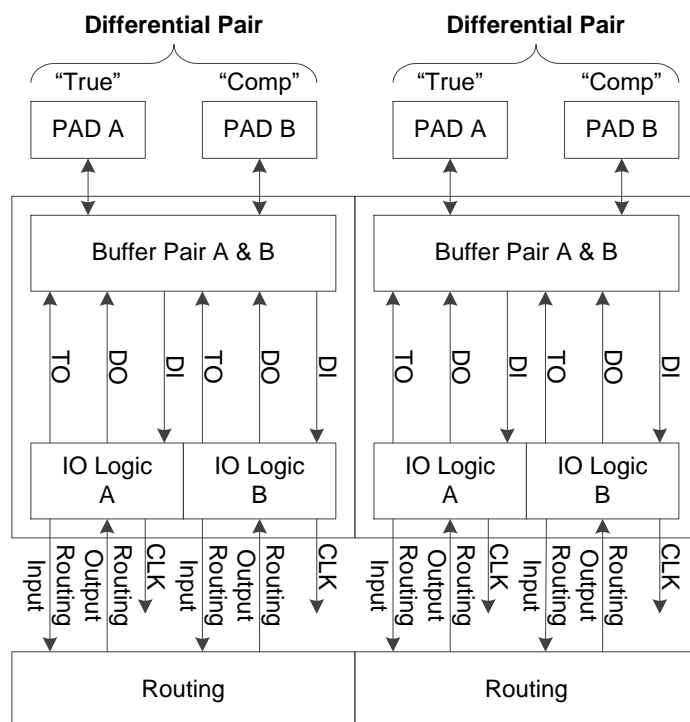
The features of the IOB include:

- V$_{CCIO}$ supplied with Each bank
- LVCMOS, PCI, LVTTL, LVDS, SSTL, HSTL, etc. Bank3 of GW1NS-4C/4 only supports single-ended LVCMOS input/output and LVDS25E differential output
- Input hysteresis options
- Drive strength options
- Individual Bus Keeper, Pull-up/Pull-down, and Open Drain options
- Hot socketing(except Bank3 of GW1NS-4C/4)
- IO logic supports basic mode, SDR mode, DDR mode, etc.
- Bank0/Bank1 of GW1NS-4C/4 support MIPI input by using MIPI IO mode.
- Bank2 of GW1NS-4C/4 support MIPI output by using MIPI IO mode.
- Bank0/Bank1/Bank2 of GW1NS-4C/4 support I3C.

2.3.1 - 2.3.4 describe I/O standards, true LVDS Design, I/O logic, and I/O logic modes. For more information about the IOB, please refer to UG289, Gowin Programmable IO (GPIO) User Guide.

2.3.1 I/O Standards

There are four I/O Banks in the GW1NS series of FPGA products, as shown in Figure 2-5. Each bank has its own I/O power supply V$_{CCIO}$. To support SSTL, HSTL, etc., Each bank also has one independent voltage source (V$_{REF}$) as the reference voltage. You can choose to use the internal V$_{REF}$ (0.5 x V$_{CCIO}$) or the external V$_{REF}$ input via any IO from the bank.

Figure 2-5 I/O Bank Distribution View of GW1NS-4C/4
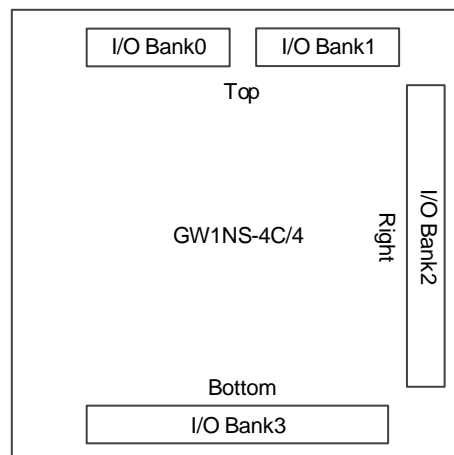
GW1NS-4C/4 support LV version only.

The LV version devices support 1.2V V_{CC} (core voltage).

V_{CCX}(auxiliary voltage) can be set to 1.8V, 2.5V, or 3.3V, and V_{CCIO}(I/O bank voltage) can be set to 1.2V, 1.5V, 1.8V, 2.5V, or 3.3V as needed.

Note!

- For GW1NS-4C/4, V_{CCIO0}/V_{CCIO1} need to be set to 1.2V when Bank0/Bank1 are used for MIPI output, and V_{CCIO2} needs to be set to 1.2V when Bank2 is used for MIPI output. The MIPI speed with V_{CCX} set to 1.8V is only 60% of the MIPI speed with V_{CCX} set to 2.5V/3.3V.

- During configuration, all GPIOs of the device are high-impedance with internal weak pull-ups. After the configuration is complete, the I/O states are controlled by user programs and constraints. The states of configuration-related I/Os differ depending on the configuration mode.

For the V_{CCIO} requirements of different I/O standards, see Table 2-1 and Table 2-2.

Table 2-1 Output I/O Standards and Configuration Options

I/O standard (output)	Single-ended /Differential	Bank V_{CCIO}(V)	Drive Strength (mA)	Typical Applications
LVCMOS33/ LVTTL33	Single-ended	3.3	4,8,12,16,24	Universal interface
LVCMOS25	Single-ended	2.5	4,8,12,16	Universal interface
LVCMOS18	Single-ended	1.8	4,8,12	Universal interface
LVCMOS15	Single-ended	1.5	4,8	Universal interface
LVCMOS12	Single-ended	1.2	4,8	Universal interface
SSTL25_I	Single-ended	2.5	8	Memory interface
SSTL25_II	Single-ended	2.5	8	Memory interface
SSTL33_I	Single-ended	3.3	8	Memory interface
SSTL33_II	Single-ended	3.3	8	Memory interface
SSTL18_I	Single-ended	1.8	8	Memory interface
SSTL18_II	Single-ended	1.8	8	Memory interface
SSTL15	Single-ended	1.5	8	Memory interface

I/O standard (output)	Single-ended /Differential	Bank V_{CCIO}(V)	Drive Strength (mA)	Typical Applications
HSTL18_I	Single-ended	1.8	8	Memory interface
HSTL18_II	Single-ended	1.8	8	Memory interface
HSTL15_I	Single-ended	1.5	8	Memory interface
PCI33	Single-ended	3.3	8/4	PC and embedded system
LVPECL33E	Differential	3.3	16	High-speed data transmission
MLVDS25E	Differential	2.5	16	LCD timing driver interface and column driver interface
BLVDS25E	Differential	2.5	16	Multi-point high-speed data transmission
RSDS25E	Differential	2.5	8	High-speed point-to-point data transmission
LVDS25E	Differential	2.5	8	High-speed point-to-point data transmission
MIPI	Differential (MIPI)	1.2	N/A	Mobile Industry Processor Interface
LVDS25	Differential (True LVDS)	2.5/3.3	N/A	High-speed point-to-point data transmission
RSDS	Differential (True LVDS)	2.5/3.3	N/A	High-speed point-to-point data transmission
MINILVDS	Differential (True LVDS)	2.5/3.3	N/A	LCD timing driver interface and column driver interface
PPLVDS	Differential (True LVDS)	2.5/3.3	N/A	LCD row/column driver
SSTL15D	Differential	1.5	8	Memory interface
SSTL25D_I	Differential	2.5	8	Memory interface
SSTL25D_II	Differential	2.5	8	Memory interface
SSTL33D_I	Differential	3.3	8	Memory interface
SSTL33D_II	Differential	3.3	8	Memory interface
SSTL18D_I	Differential	1.8	8	Memory interface
SSTL18D_II	Differential	1.8	8	Memory interface
HSTL18D_I	Differential	1.8	8	Memory interface
HSTL18D_II	Differential	1.8	8	Memory interface
HSTL15D_I	Differential	1.5	8	Memory interface
LVCMOS12D	Differential	1.2	4,8	Universal interface
LVCMOS15D	Differential	1.5	4,8	Universal interface
LVCMOS18D	Differential	1.8	4,8,12	Universal interface
LVCMOS25D	Differential	2.5	4,8,12,16	Universal interface

I/O standard (output)	Single-ended /Differential	Bank V$_{CCIO}$(V)	Drive Strength (mA)	Typical Applications
LVCMOS33D	Differential	3.3	4,8,12,16,24	Universal interface

Note!

Bank3 of GW1NS-4C/4 only supports single-ended LVCMOS output and LVDS25E differential output.

Table 2-2 Input I/O Standards and Configuration Options

I/O standard (input)	Single-ended/Differential	Bank V$_{CCIO}$(V)	Supports Hysteresis Options?	Needs V$_{REF}$?
LVCMOS33/ LVTTL33	Single-ended	1.2/1.5/1.8/2.5/3.3	Yes	No
LVCMOS25	Single-ended	1.2/1.5/1.8/2.5/3.3	Yes	No
LVCMOS18	Single-ended	1.2/1.5/1.8/2.5/3.3	Yes	No
LVCMOS15	Single-ended	1.2/1.5/1.8/2.5/3.3	Yes	No
LVCMOS12	Single-ended	1.2/1.5/1.8/2.5/3.3	Yes	No
SSTL15	Single-ended	1.5/1.8/2.5/3.3	No	Yes
SSTL25_I	Single-ended	2.5/3.3	No	Yes
SSTL25_II	Single-ended	2.5/3.3	No	Yes
SSTL33_I	Single-ended	3.3	No	Yes
SSTL33_II	Single-ended	3.3	No	Yes
SSTL18_I	Single-ended	1.8/2.5/3.3	No	Yes
SSTL18_II	Single-ended	1.8/2.5/3.3	No	Yes
HSTL18_I	Single-ended	1.8/2.5/3.3	No	Yes
HSTL18_II	Single-ended	1.8/2.5/3.3	No	Yes
HSTL15_I	Single-ended	1.5/1.8/2.5/3.3	No	Yes
LVCMOS33OD25	Single-ended	2.5	No	No
LVCMOS33OD18	Single-ended	1.8	No	No
LVCMOS33OD15	Single-ended	1.5	No	No
LVCMOS25OD18	Single-ended	1.8	No	No
LVCMOS25OD15	Single-ended	1.5	No	No
LVCMOS18OD15	Single-ended	1.5	No	No
LVCMOS15OD12	Single-ended	1.2	No	No

I/O standard (input)	Single-ended/Differential	Bank V_{CCIO}(V)	Supports Hysteresis Options?	Needs V_{REF}?
LVCMOS25UD33	Single-ended	3.3	No	No
LVCMOS18UD25	Single-ended	2.5	No	No
LVCMOS18UD33	Single-ended	3.3	No	No
LVCMOS15UD18	Single-ended	1.8	No	No
LVCMOS15UD25	Single-ended	2.5	No	No
LVCMOS15UD33	Single-ended	3.3	No	No
LVCMOS12UD15	Single-ended	1.5	No	No
LVCMOS12UD18	Single-ended	1.8	No	No
LVCMOS12UD25	Single-ended	2.5	No	No
LVCMOS12UD33	Single-ended	3.3	No	No
PCI33	Single-ended	3.3	Yes	No
VREF1_DRIVER	Single-ended (Vref Input)	1.2/1.5/1.8/2.5/3.3	No	Yes
MIPI	Differential (MIPI)	1.2	No	No
LVDS25	Differential	2.5/3.3	No	No
RSDS	Differential	2.5/3.3	No	No
MINILVDS	Differential	2.5/3.3	No	No
PPLVDS	Differential	2.5/3.3	No	No
LVDS25E	Differential	2.5/3.3	No	No
MLVDS25E	Differential	2.5/3.3	No	No
BLVDS25E	Differential	2.5/3.3	No	No
RSDS25E	Differential	2.5/3.3	No	No
LVPECL33E	Differential	3.3	No	No
SSTL15D	Differential	1.5/1.8/2.5/3.3	No	No
SSTL25D_I	Differential	2.5/3.3	No	No
SSTL25D_II	Differential	2.5/3.3	No	No
SSTL33D_I	Differential	3.3	No	No
SSTL33D_II	Differential	3.3	No	No
SSTL18D_I	Differential	1.8/2.5/3.3	No	No
SSTL18D_II	Differential	1.8/2.5/3.3	No	No
HSTL18D_I	Differential	1.8/2.5/3.3	No	No
HSTL18D_II	Differential	1.8/2.5/3.3	No	No
HSTL15D_I	Differential	1.5/1.8/2.5/3.3	No	No

I/O standard (input)	Single-ended/Differential	Bank V_{CCIO}(V)	Supports Hysteresis Options?	Needs V_{REF}?
LVCMOS12D	Differential	1.2/1.5/1.8/2.5/3.3	No	No
LVCMOS15D	Differential	1.5/1.8/2.5/3.3	No	No
LVCMOS18D	Differential	1.8/2.5/3.3	No	No
LVCMOS25D	Differential	2.5/3.3	No	No
LVCMOS33D	Differential	3.3	No	No

Note!

Bank3 of GW1NS-4C/4 only supports single-ended LVCMOS input.

2.3.2 True LVDS Design

Bank2 of GW1NS-4/4C supports true LVDS output. In addition, the GW1NS series of FPGA products support LVDS25E, MLVDS25E, BLVDS25E, etc.

For more information about true LVDS, see <u>UG824, GW1NS-4&4C Pinout</u>.

True LVDS input needs a 100Ω termination resistor, see Figure 2-6 for the reference design. Bank0/1 of the GW1NS-4/4C device support programmable on-chip 100Ω input differential termination resistors, see <u>UG289, Gowin Programmable IO (GPIO) User Guide</u>.

Figure 2-6 True LVDS Design
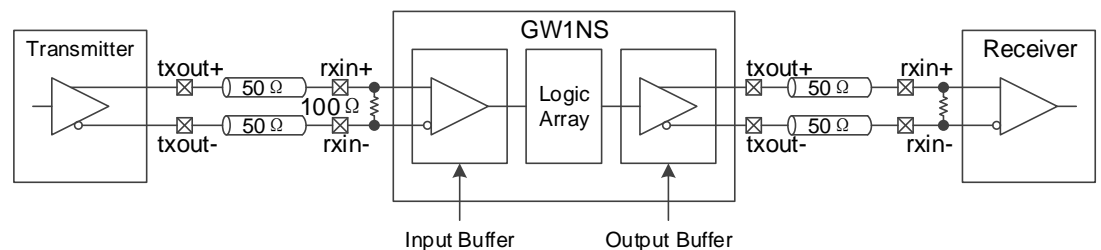
For information about termination for LVDS25E, MLVDS25E, and BLVDS25E, please refer to <u>UG289, Gowin Programmable IO (GPIO) User Guide</u>.

2.3.3 I/O Logic

Figure 2-7 shows the I/O logic input and output of the GW1NS series of FPGA products.

Figure 2-7 I/O Logic Input and Output
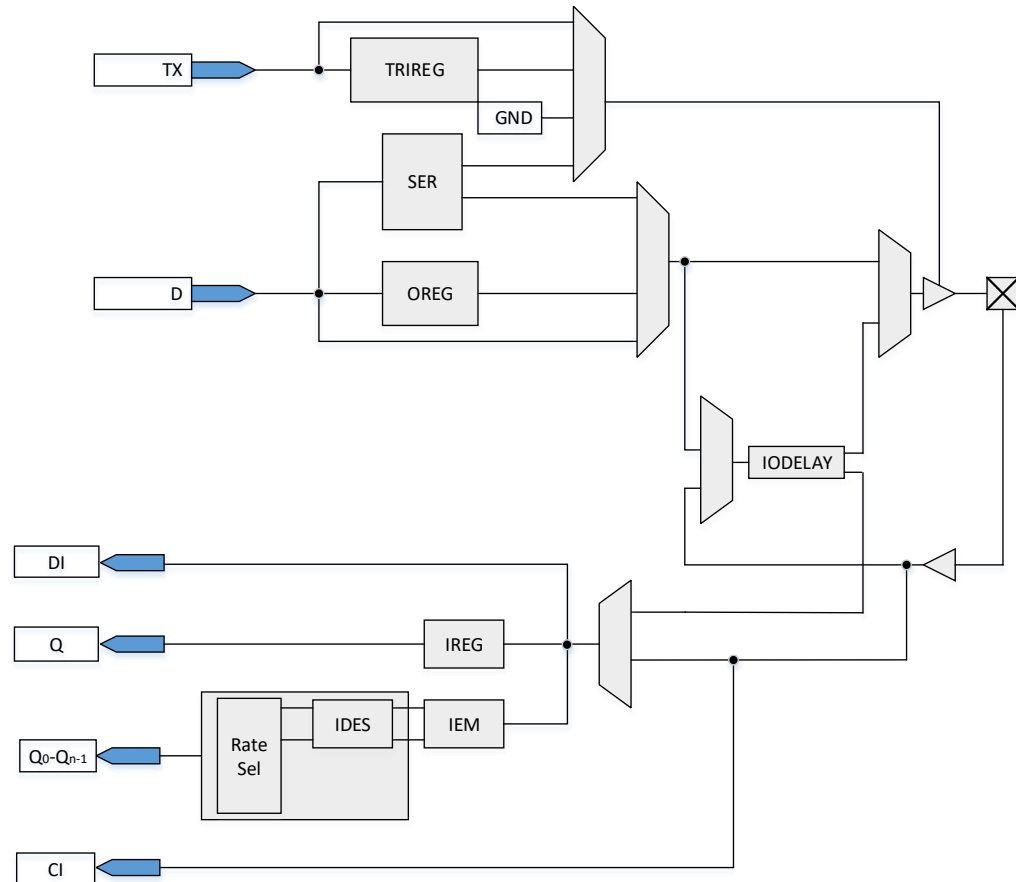
Table 2-3 Port Description

Port	I/O	Description
CI[1]	Input	GCLK input signal. For the number of GCLK input signals, please refer to UG824, GW1NS-4&4C Pinout.
DI	Input	IO port low-speed input signal input into the fabric directly.
Q	Output	IREG output signal in the SDR module.
Q_0-Q_{n-1}	Output	IDES output signal in the DDR module.

Note!

When CI is used as GCLK input, DI, Q, and Q0-Qn-1 cannot be used as I/O input and output.

Descriptions of the I/O logic modules of the GW1NS series of FPGA products are presented below.

IODELAY

See Table 2-4 Total Delay of IODELAY Module

	Min. (ps)	Typ. (ps)	Max. (ps)
Tdlyoffset	450	500	550
Tdlyunit	-	30	-
DLYSTEP	0	-	127

Figure 2-8 for an overview of the IODELAY module. Each I/O of the GW1N series of FPGA products contains the IODELAY module, through which you can add additional delays to the I/O to adjust the delay of the signal. The delay time of each step is $T_{dlyunit}$, and the number of steps is DLYSTEP. The total delay time of IODELAY can be calculated as follows: $T_{maxdly} = T_{dlyoffset} + T_{dlyunit} * DLYSTEP$. See Table 2-4 for the total delay time.

Table 2-4 Total Delay of IODELAY Module

	Min. (ps)	Typ. (ps)	Max. (ps)
$T_{dlyoffset}$	450	500	550
$T_{dlyunit}$	-	30	-
DLYSTEP	0	-	127

Figure 2-8 IODELAY Diagram
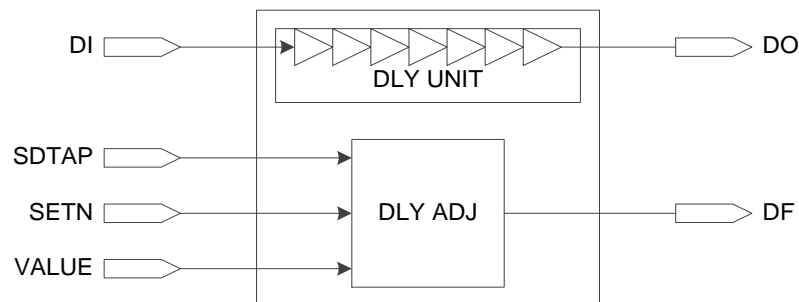
There are two ways to control the delay:

- Static control.
- Dynamic control: can be used with the IEM module to adjust the dynamic sampling window. The IODELAY module cannot be used for both input and output at the same time.

I/O Register

See Figure 2-9 for the I/O register in the GW1NS series of FPGA products. Each I/O provides one input register (IREG), one output register (OREG), and one tristate register (TRIREG).

Figure 2-9 I/O Register Diagram
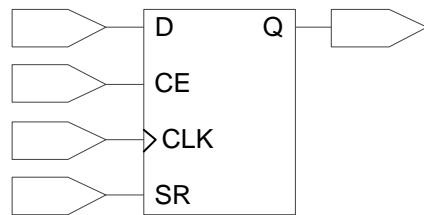
Note!

- CE can be programmed as either active low (0: enable) or active high (1: enable).

- CLK can be programmed as either rising edge triggering or falling edge triggering.

- SR can be programmed as either synchronous/asynchronous SET/RESET or disabled.

- The register can be programmed as a register or a latch.

IEM

The IEM(Input Edge Monitor) module is used to sample data edges and is used in generic DDR mode, as shown in Figure 2-10.

Figure 2-10 IEM Diagram
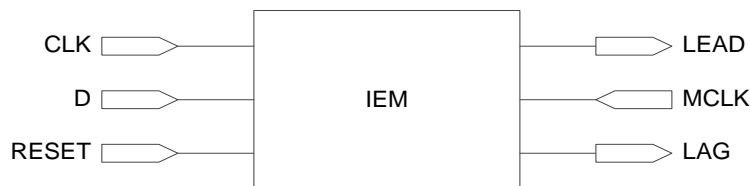
DES

This series of FPGA products provide a simple deserializer(DES) for input I/O logic to support advanced I/O protocols.

SER

This series of FPGA products provide a simple serializer(SER) for output I/O logic to support advanced I/O protocols.

2.3.4 I/O Logic Modes

The I/O Logic of the GW1NS series of FPGA products supports several operation modes. In each operation mode, the I/O (or I/O differential pair) can be configured as output, input, INOUT or tristate output (output signal with tristate control).

2.4 Block SRAM

2.4.1 Introduction

The GW1NS series of FPGA products provide abundant block SRAM resources. These memory resources are distributed as blocks throughout the FPGA array in the form of rows. Therefore, they are called block static random access memories (BSRAMs). Each BSRAM block occupies 3 CLU locations.

BSRAMs serve two main purposes.

1. They function as the SRAM resources for the Cortex-M3 processor system. The capacity of a BSRAM when used as the SRAM for Cortex-M3 is 16Kbits (2K-Byte). The Gowin software supports the configuration of SRAM resources, offering options like 2K-Byte, 4K-Byte, and 8K-Byte. Any unused BSRAMs are available for user storage.
2. BSRAMs can be utilized for user storage. In this case, the capacity of a BSRAM is up to 18Kbits and multiple configuration modes and operation modes are supported.

An abundance of BSRAM resources provide a guarantee for the user's high-performance design. The features of BSRAMs include:

- Up to 18,432 bits per BSRAM
- Clock frequency up to 190MHz
- Supports Single Port mode
- Supports Dual Port mode
- Supports Semi-Dual Port mode
- Provides parity bits
- Supports ROM Mode
- Data widths from 1 to 36 bits
- Mixed clock mode
- Mixed data width mode
- Byte Enable function for 2-byte and above data widths
- Asynchronous reset, and can be released synchronously
- Normal read and write
- Read-before-write
- Write-through

2.4.2 Memory Configuration Modes

BSRAMs in the GW1NS series of FPGA products support various data widths, see Table 2-5.

Table 2-5 Memory Size Configuration

Single Port Mode	Dual Port Mode[1]	Semi-Dual Port Mode	ROM Mode
16K x 1	16K x 1	16K x 1	16K x 1
8K x 2	8K x 2	8K x 2	8K x 2
4K x 4	4K x 4	4K x 4	4K x 4
2K x 8	2K x 8	2K x 8	2K x 8
1K x 16	1K x 16	1K x 16	1K x 16
512 x 32	-	512 x 32	512 x 32
2K x 9	2K x 9	2K x 9	2K x 9
1K x 18	1K x 18	1K x 18	1K x 18
512 x 36	-	512 x 36	512 x 36

Note!

[1] GW1NS-4C/4 does not support dual port mode.

Single Port Mode

The single port mode supports 2 read modes (bypass mode and pipeline mode) and 3 write modes (normal mode, write-through mode, and read-before-write mode). In single port mode, writing to or reading from one port at one clock edge is supported. During the write operation, the written data will be transferred to the output of the BSRAM. When the output register is bypassed, the new data will show up at the same write clock rising edge.

For more information on single port mode, please refer to UG285, Gowin BSRAM & SSRAM User Guide.

Dual Port Mode

The dual port mode supports 2 read modes (bypass mode and pipeline mode) and 2 write modes (normal mode and write-through mode). The applicable operations are as follows:

- Two independent read operations
- Two independent write operations
- An independent read operation and an independent write operation

Note!

It is not recommended to perform simultaneous read access from one port and write access from the other port to the same memory address.

For more information on dual port mode, please refer to UG285, Gowin BSRAM & SSRAM User Guide.

Semi-Dual Port Mode

The semi-dual port mode supports 2 read modes (bypass mode and pipeline mode) and 1 write mode (normal mode). Semi-dual port mode supports simultaneous read and write operations in the form of writing to port A and reading from port B.

Note!

It is not recommended to perform simultaneous read access from one port and write access from the other port to the same memory address.

For more information on semi-dual port mode, please refer to UG285, Gowin BSRAM & SSRAM User Guide.

ROM Mode

BSRAMs can be configured as ROMs. The ROM can be initialized during the device configuration stage, and the ROM data needs to be provided in the initialization file. Initialization is completed during the device power-on process.

Each BSRAM can be configured as one 16Kbits ROM. For more information on ROM mode, please refer to UG285, Gowin BSRAM & SSRAM User Guide.

2.4.3 Mixed Data Width Configuration

The BSRAMs in the GW1NS series of FPGA products support mixed data width operations. In dual port mode and semi-dual port mode, the data widths for read and write can be different, see Table 2-6 and Table 2-7.

Table 2-6 Dual Port Mixed Read/Write Data Width Configuration

Read Port	Write Port						
	16K x 1	8K x 2	4K x 4	2K x 8	1K x 16	2K x 9	1K x 18
16K x 1	Yes	Yes	Yes	Yes	Yes	N/A	N/A
8K x 2	Yes	Yes	Yes	Yes	Yes	N/A	N/A
4K x 4	Yes	Yes	Yes	Yes	Yes	N/A	N/A
2K x 8	Yes	Yes	Yes	Yes	Yes	N/A	N/A
1K x 16	Yes	Yes	Yes	Yes	Yes	N/A	N/A
2K x 9	N/A	N/A	N/A	N/A	N/A	Yes	Yes
1K x 18	N/A	N/A	N/A	N/A	N/A	Yes	Yes

Note!

GW1NS-4C/4 does not support dual port mode.

Table 2-7 Semi-dual Port Mixed Read/Write Data Width Configuration

Read Port	Write Port								
	16K x 1	8K x 2	4K x 4	2K x 8	1K x 16	512 x 32	2K x 9	1K x 18	512 x 36
16K x 1	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A
8K x 2	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A
4K x 4	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A
2K x 8	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A
1K x 16	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A
512x32	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A
2K x 9	N/A	N/A	N/A	N/A	N/A	N/A	Yes	Yes	Yes
1K x 18	N/A	N/A	N/A	N/A	N/A	N/A	Yes	Yes	Yes

2.4.4 Parity Bit

There are parity bits in BSRAMs. The 9th bit in each byte can be used as a parity bit to check the correctness of data transmission. It can also be used for data storage.

2.4.5 Synchronous Operation

- All the input registers of BSRAMs support synchronous write.
- The output registers can be used as pipeline registers to improve design performance.
- The output registers are bypass-able.

2.4.6 BSRAM Operation Modes

The BSRAM supports five different operations, including two read modes (Bypass mode and Pipeline mode) and three write modes (Normal mode, Write-Through mode, and Read-before-Write mode).

Read Mode

The following two read modes are supported.

PIPELINE MODE

When a synchronous write cycles into a memory array with pipeline registers enabled, the data can be read from pipeline registers in the next clock cycle. The data bus can be up to 36 bits in this mode.

BYPASS MODE

When a synchronous write cycles into a memory array with pipeline registers bypassed, the outputs are registered at the memory array.

Figure 2-11 Pipeline Mode in Single Port Mode, Dual Port Mode, and Semi-dual

Port Mode
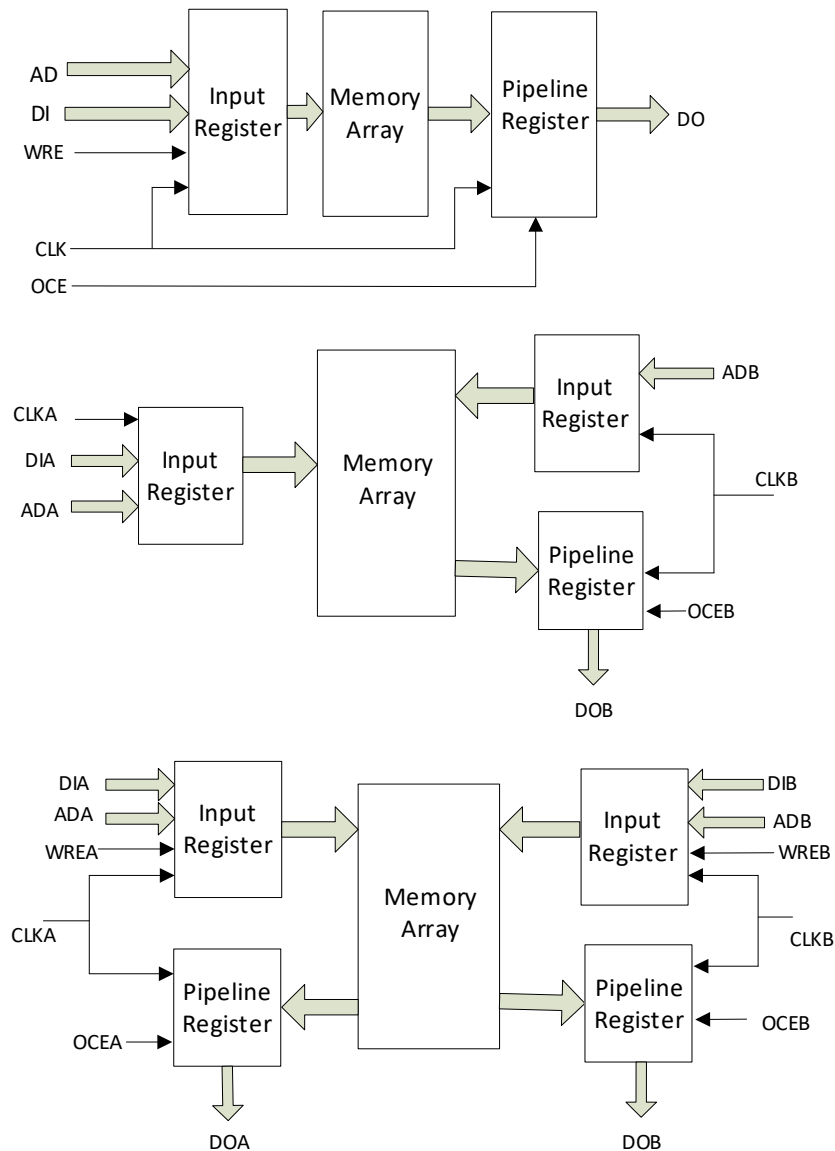
Write Mode

NORMAL MODE

In this mode, when you write data to one port, the output data of this port does not change. The written data will not appear at the read port.

WRITE-THROUGH MODE

In this mode, when you write data to one port, the written data will appear at the output of this port.

READ-BEFORE-WRITE MODE

In this mode, when you write data to one port, the written data will be stored in the memory according to the address, and the original data in this address will appear at the output of this port.

2.4.7 Clock Mode

Table 2-8 lists the clock modes in different BSRAM modes:

Table 2-8 Clock Modes in Different BSRAM Modes

Clock Mode	Dual Port Mode[1]	Semi-Dual Port Mode	Single Port Mode
Independent Clock Mode	Yes	No	No
Read/Write Clock Mode	Yes	Yes	No
Single Port Clock Mode	No	No	Yes

Note!

[1] GW1NS-4C/4 does not support dual port mode.

Independent Clock Mode

Figure 2-12 shows the independent clock operation in dual port mode with one clock at each port. CLKA controls all the registers at Port A; CLKB controls all the registers at Port B.

Figure 2-12 Independent Clock Mode
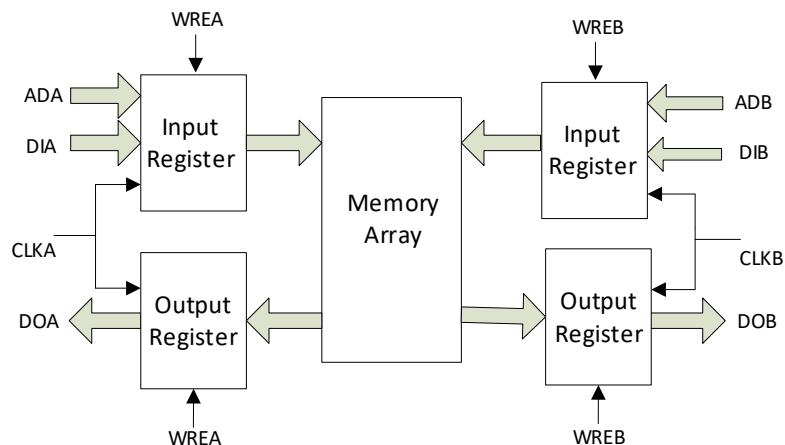
Read/Write Clock Mode

Figure 2-13 shows the read/write clock operation in semi-dual port mode with one clock at each port. The write clock (CLKA) controls data inputs, write addresses and read/write enable signals of Port A. The read clock (CLKB) controls data outputs, read addresses, and read enable signals of Port B.

Figure 2-13 Read/Write Clock Mode
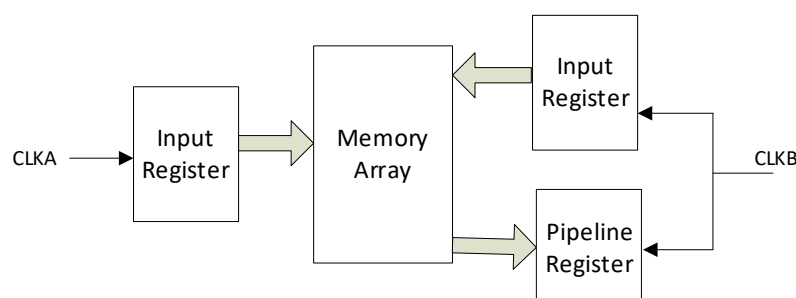
Single Port Clock Mode

Figure 2-14 shows the clock operation in single port mode.

Figure 2-14 Single Port Clock Mode
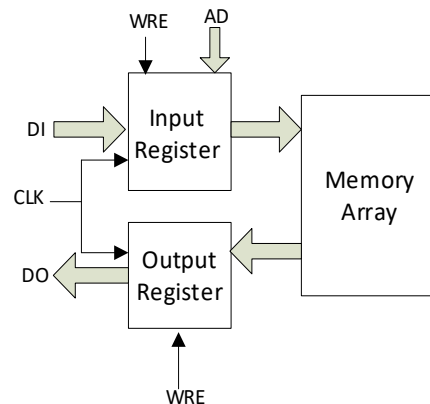
2.5 User Flash (GW1NS-4)

2.5.1 Introduction

The capacity of the User Flash in GW1NS-4 is 32KB. The User Flash consists of row memories and column memories. One row memory consists of 64 column memories. The capacity of one column memory is 32 bits, and the capacity of one row memory is 64*32=2048 bits. Page erase is supported, and the capacity of one page is 2048 bytes, that is, one page contains 8 rows. The key features include:

- NOR Flash
- 10,000 write cycles
- Greater than 10 years of data retention at +85℃
- Data width: 32 bits
- Capacity: 128 rows x 64 columns x 32 = 256K bits
- Page erase capability: 2,048 bytes per page
- Fast Page Erase/Word Program Operation
- Clock frequency: 40 MHz
- Word Program Time: ≤16μs
- Page Erase Time: ≤120 ms
- Current
    - Read current/duration: 2.19mA/25ns (V_{CC}) & 0.5mA/25ns (V_{CCX})(MAX)
    - Program/erase operation: 12/12mA(MAX)

Note!

For more information about the User Flash in GW1NS-4, please refer to UG295, Gowin User Flash User Guide. For the correspondence between User Flash primitives and devices supported, please refer to Table 3-1 Devices Supported of UG295, Gowin User Flash User Guide.

2.6 Digital Signal Processing

2.6.1 Introduction

GW1NS-4C/4 provide abundant DSP resources. Gowin's DSP solutions can address high-performance digital signal processing needs such as FIR and FFT designs. The DSP resources have the advantages of stable timing performance, high resource utilization, and low power consumption.

The DSP resources offer the following functions:

- Multipliers with three widths: 9-bit, 18-bit, 36-bit
- 54-bit ALU
- Multipliers cascading to support wider data widths
- Barrel shifters
- Adaptive filtering through signal feedback
- Computing with options to round to a positive number or a prime number
- Supports pipeline mode and bypass mode.

2.6.2 Macro

The DSP blocks are distributed throughout the FPGA array in the form of rows. Each DSP block occupies 9 CLU locations. Each DSP block contains two macros, and each macro contains two pre-adders, two 18 x 18 bit multipliers, and one three-input ALU.

Pre-adder

Each DSP macro contains two pre-adders for implementing pre-addition, pre-subtraction, and shifting.

The pre-adders are located at the first stage with two input ports:

- Parallel 18-bit input B or SIB;
- Parallel 18-bit input A or SIA.

Note!

Each input port supports pipeline mode and bypass mode.

Gowin's pre-adders can be used independently as function blocks, which support 9-bit and 18-bit width.

Multiplier

The multipliers are located after the pre-adders. The multipliers can be configured as 9 x 9, 18 x 18, 36 x 18, or 36 x 36. Register mode and bypass mode are supported in both input and output ports. The configuration modes that a macro supports include:

- One 18 x 36 multiplier
- Two 18 x 18 multipliers
- Four 9 x 9 multipliers

Note!

Two macros can form one 36 x 36 multiplier.

Arithmetic Logic Unit

Each DSP macro contains one 54-bit ALU, which can further enhance multipliers' functions. Register mode and bypass mode are supported in both input and output ports. The functions include:

- Addition/subtraction operations of multiplier output data/0, data A, and data B.
- Addition/subtraction operations of multiplier output data/0, data B, and carry C.
- Addition/subtraction operations of data A, data B, and carry C.

2.6.3 DSP Operation Modes

- Multiplier mode
- Multiply accumulator mode
- Multiply-add accumulator mode

For more information, see UG287, Gowin Digital Signal Processing (DSP) User Guide.

2.7 Cortex-M3

2.7.1 Introduction

GW1NS-4C is a system-on-chip FPGA device that incorporates a microprocessor system hard core, abundant logic resources, and BSRAM resources, built-in PLL and OSC. The embedded microprocessor system contains a low-power, low-cost and high-performance ARM Cortex-M3 32-bit RISC. The flexible FPGA fabric serves as user programmable peripherals, or soft-core IPs.

The embedded microprocessor system consists of the processor block, with ARM Cortex-M3 32-bit RISC core and associated supporting bus system that connects to harden standard peripherals. The FPGA fabric contains rich programmable logic resources that allow the user to employ peripherals with the microprocessor system. This can be achieved either by parameterized soft-core IPs or customized Verilog design. The microprosessor system only interfaces with the FPGA fabric and JTAG config-core internally with no access to the I/O Blocks.

The bus system consists of AHB-Lite Bus, AHB2APB Bridge, and two APB Bus: APB1 and APB2.

The microprocessor system relies on AHB bus to access FPGA side sub-memory system which has a pre-implemented sub-memory system controller for read-only-access 128 KB Flash-ROM and read/write-access 8 KB BSRAM. Upon Power-On boot loading, Cortex-M3 loads instructions and data that are pre-stored in the Flash-ROM, and transfers it to the BSRAM before initiating the execution.

In addition, there are two AHB bus extension ports: INTEXP0 and TARGEXP0. Each of these AHB extension ports provides a 32 bits AHB bus interconnecting to any high-speed User programmable peripherals implemented within the FPGA. A GPIO block interconnects the AHB bus with the FPGA fabric to allow the user to implement general purpose I/O

functions in FPGA.

In terms of the two APB Bus (APB1 and APB2), APB1 interconnects with two timers (Timer0 and Timer1), two UARTs (Uart0 and Uart1), and one watchdog. Two UARTs connect to the FPGA directly. The two timers and the watchdog are controlled and used within the microprocessor system and are accessed through REG. The APB2 bus connects directly to the FPGA.

The processor block consists of Cortex-M3 core, bus matrix, Nested Vector Interrupt Controller (NVIC), Debug Access Port (DAP), and time stamp.

The Cortex-M3 core relies on the bus-matrix to access its supporting bus system (AHB-Lite Bus, AHB2APB Bridge, and two APB Bus: APB1 and APB2).

NVIC of GW1NS-4C offers six external user defined interrupts. The DAP contains JTAG DAP and also Trace-Port-Interface-Unit (TPIU).

The Microprocessor System also provides an interrupt monitor signal, which combines GPIO interrupts as well as APB1 peripherals (UART0, UART1, Timer0, Timer1, Watchdog) interrupts, back to the FPGA fabric to report the current run-time interrupt Status of the Microprocessor System.

FPGA fabric takes advantage of its rich Clocking Resource (PLL, OSC) and provides the Main Clock, Power-On Reset and System Reset signals to the embedded microprocessor system.

See Figure 2-15 for the Cortex-M3 architecture.

Figure 2-15 Cortex-M3 Architecture
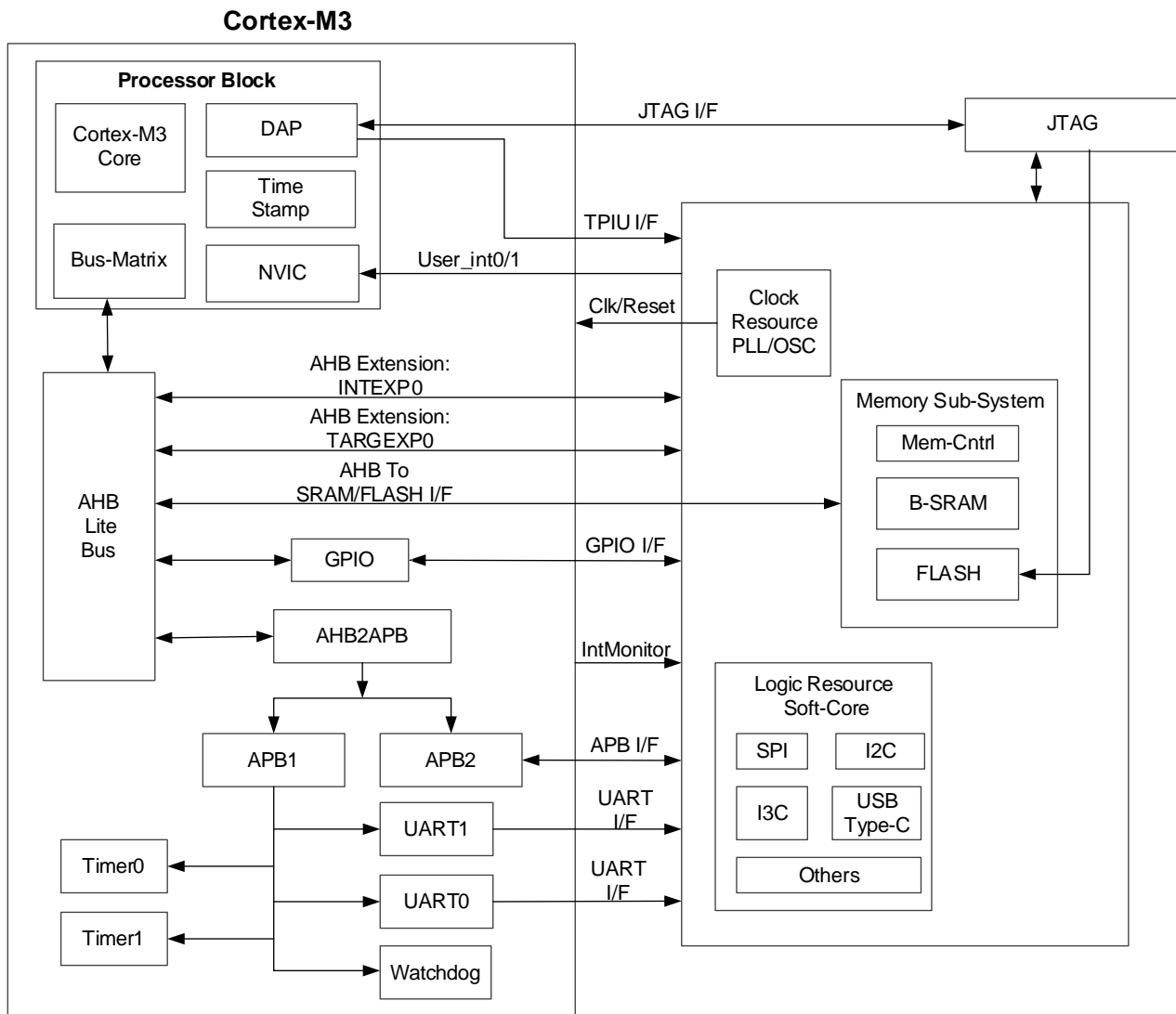
2.7.2 Cortex-M3

Features of the microprocessor system are as follows:

- Compact core
- Thumb-2 instruction set, delivering the high-performance expected of an ARM core in the memory size usually
- Associated with 8 bits and 16 bits devices; typically, in the range of a few kilobytes of memory for microcontroller class applications
- Rapid application execution through Harvard architecture characterized by separate buses for instruction and data
- Achieves exceptional interrupt handling, by implementing the register manipulations required for handling an interrupt in hardware.
- Deterministic, fast interrupt processing.
- Memory protection unit (MPU), providing a privileged mode for protecting operation system functionality
- Migration from the ARM7™ processor family for better performance and power efficiency
- Full-featured debug solution

–   JTAG Debug Port (JTAG)
–   Flash Patch and Breakpoint (FPB) unit for implementing breakpoints
–   Data Watchpoint and Trigger (DWT) unit for implementing watchpoints, trigger resources, and system profiling
–   Instrumentation Trace Macrocell (ITM) for support of print style debugging
–   Trace Port Interface Unit (TPIU) for bridging to a Trace Port Analyzer

2.7.3 Bus-Matrix

The bus-matrix is used to connect the Cortex-M3 processor and debug port with an external AHB bus.

Connections between bus-matrix and AHB bus:

● ICode bus: 32bit AHBLite bus, used for fetching instructions and vectors from code space;
● DCode bus: 32bit AHBLite bus, used for data loading/storage and debug access;
● System bus: 32bit AHBLite bus, used for fetching instructions and vectors from system space, data loading/storage and debug access;
● APB: 32bit APB bus, used for external space data loading/storage and debug access.

The bus-matrix controls the following functions as below:

● Unaligned accesses: Converts the unaligned processor access to aligned access;
● Bit-banding: converts the alias access of Bit_band to Bit_band space access;
● Write buffer: Bus-matrix contains one write-buffer, ensuring that the processor core is not affected by bus delay.

2.7.4 NVIC

NVIC features:

● Supports low-latency interrupt processing up to 26 interrupts

● GW1NS-4C supports six external user defined interrupts

● A programmable priority level of 0-7 for each interrupt; a higher level corresponds to a lower priority; as such level 0 is the highest interrupt priority

● Low-latency exception and interrupt handling

● Dynamic reprioritization of interrupts

● The processor automatically stacks its state on exception entry and unstacks this state on exception exit, with no instruction overhead.

Table 2-9 NVIC Address Table

Address	Name	Type	Description
0x00000000	_StackTop	Read only	Top of stack interrupt

Address	Name	Type	Description
0x00000004	Reset_Handler	Read only	Reset interrupt
0x00000008	NMI_Handler	Read only	NMI interrupt
0x0000000C	HardFault_Handler	Read only	Hard fault interrupt
0x00000010	MemMange_Handler	Read only	MPU fault interrupt
0x00000014	BusFault_Handler	Read/Write	Bus fault interrupt
0x00000018	UsageFault_Handler	Read only	Usage fault interrupt
0x0000002C	SVC_Handler	Read/Write	SVCall interrupt
0x00000030	DebugMon_Handler	Read only	Debug monitor interrupt
0x00000038	PendSV_Handler	Read / Write / Read only	Pending interrupt
0x0000003C	SysTick_Handler	Read/Write	System timer interrupt
External interrupt (GW1NS-4C)			
0x00000040	UART0_Handler	Read/Write	UART0 reception and sending interrupt
0x00000044	USER_INT0_Handler	Read/Write	User defined interrupt 0
0x00000048	UART1_Handler	Read/Write	UART1 reception and sending interrupt
0x0000004C	USER_INT1_Handler	Read/Write	User defined interrupt 1
0x00000050	USER_INT2_Handler	Read/Write	User defined interrupt 2
0x00000058	PORT0_COMB_Handler	Read/Write	GPIO0 interrupt
0x0000005C	USER_INT3_Handler	Read/Write	User defined interrupt 3
0x00000060	TIMER0_Handler	Read/Write	TIMER0 interrupt
0x00000064	TIMER1_Handler	Read/Write	TIMER1 interrupt
0x0000006C	I2C_Handler	Read/Write	I2C interrupt
0x00000070	UARTOVF_Handler	Read/Write	UART0/UART1 overflow interrupt
0x00000074	USER_INT4_Handler	Read/Write	User defined interrupt 4
0x00000078	USER_INT5_Handler	Read/Write	User defined interrupt 5
0x00000080	PORT0_0_Handler	Read/Write	GPIO0 Pin 0 interrupt
0x00000084	PORT0_1_Handler	Read/Write	GPIO0 Pin 1 interrupt
0x00000088	PORT0_2_Handler	Read/Write	GPIO0 Pin 2 interrupt
0x0000008C	PORT0_3_Handler	Read/Write	GPIO0 Pin 3 interrupt
0x00000090	PORT0_4_Handler	Read/Write	GPIO0 Pin 4 interrupt
0x00000094	PORT0_5_Handler	Read/Write	GPIO0 Pin 5 interrupt
0x00000098	PORT0_6_Handler	Read/Write	GPIO0 Pin 6 interrupt
0x0000009C	PORT0_7_Handler	Read/Write	GPIO0 Pin 7 interrupt
0x000000A0	PORT0_8_Handler	Read/Write	GPIO0 Pin 8 interrupt
0x000000A4	PORT0_9_Handler	Read/Write	GPIO0 Pin 9 interrupt
0x000000A8	PORT0_10_Handler	Read/Write	GPIO0 Pin 10 interrupt
0x000000AC	PORT0_11_Handler	Read/Write	GPIO0 Pin 11 interrupt

Address	Name	Type	Description
0x000000B0	PORT0_12_Handler	Read/Write	GPIO0 Pin 12 interrupt
0x000000B4	PORT0_13_Handler	Read/Write	GPIO0 Pin 13 interrupt
0x000000B8	PORT0_14_Handler	Read/Write	GPIO0 Pin 14 interrupt
0x000000BC	PORT0_15_Handler	Read/Write	GPIO0 Pin 15 interrupt

2.7.5 Boot Loader

The boot loader loads the initial stack pointer value from the program memory, and branches to the reset handler that the reset vector specifies in the program memory.

The current boot loader is based on UART Message Monitor which is easy to interface as a communication port with PC host. Below is an example of how to deploy the boot loader:

- Power-on reset to enter the reset handler to call the boot loader;
- Setup UART0 registers, such as BAUDIV and CTRL, to program the appropriate TX speed rate for the send and receive function;
- Begin Flash loader subroutine execution such as memory test, timer0, and timer1 tests etc;
- Write a 0x4 character (EOP) to terminate the program.

2.7.6 TimeStamp

A 48-bit timestamp counter is included and connected to the ITM. It is clock gated and enabled by the Trace Enable (TRCENA) bit of DEMCR (0xE000EDFC) Debug Exception and monitor control register, which is a global enable bit that enables both the Data Watch Trace (DWT) and Intrumental Trace Module (ITM) on behalf of the debug of the Cortex-M3 microprocessor. The time stamp generator is used during the debug process to set up the break point and marching step, etc.

Figure 2-16 DEMCR Register
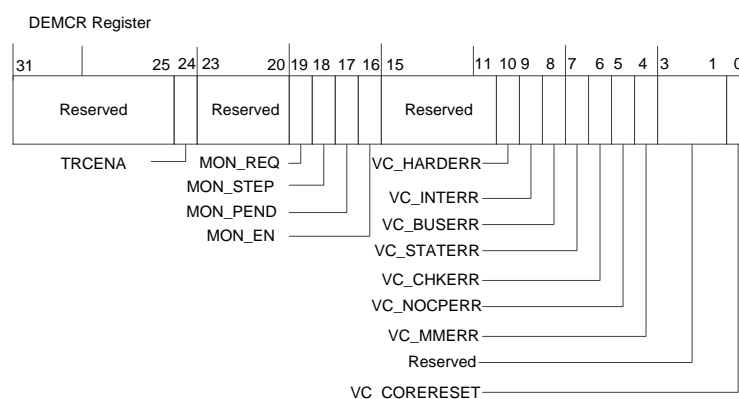
Note!

TRCENA is the global enable for DWT and ITM features:

- 0: DWT and ITM units disabled.
- 1: DWT and ITM units enabled.

2.7.7 Timer

GW1NS-4C offers an embedded microprocessor system that contains two synchronous standard timers: Timer0 and Timer1. These can be accessed and controlled through APB1 bus.

Timer0 and Timer1 are 32 bits down-counter with the following features:

- Users can generate an interrupt request signal, TIMERINT, when the counter reaches 0. The interrupt request is held until it is cleared by writing to the INTCLEAR Register.
- Users can employ the zero-to-one transition of the external input signal, EXTIN, as a timer enable.
- If the timer count reaches 0 and, at the same time, the software clears a previous interrupt status, the interrupt status is set to 1.
- The external clock, EXTIN, must be slower than half of the peripheral clock because it is sampled by a double flip-flop before going through edge-detection logic when the external inputs act as a clock.
- Timer0: EXTIN is hard-wired to GPIO[1]
- Timer1: EXTIN is hard-wired to GPIO[6]

Figure 2-17 Timer0 / Timer1 Structure View
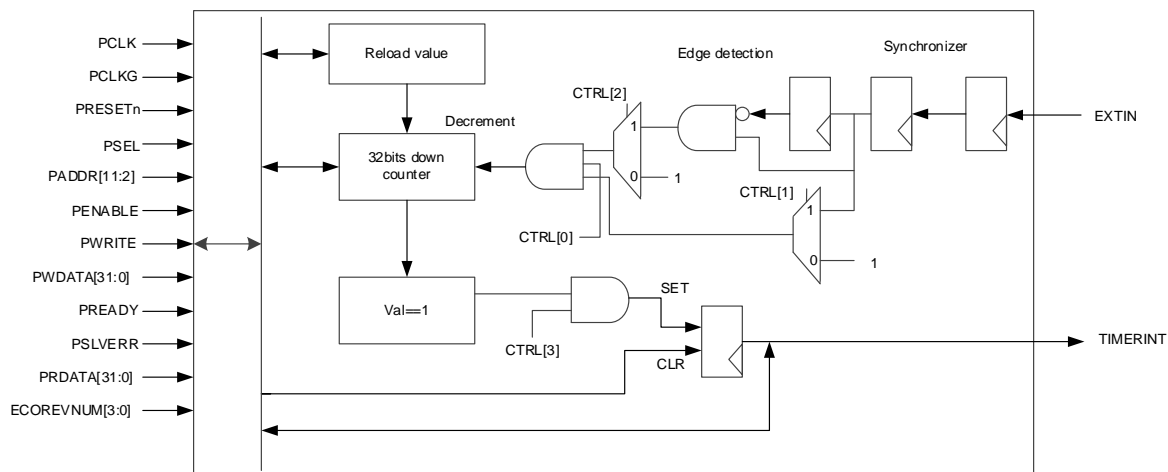
The Timer0/Timer1 register is as shown in Table 2-10. The Timer0 base address is 0x40000000, and the Timer1 base address is 0x40001000.

Table 2-10 Timer0/Timer1 Register

Name	Base Offset	Type	Data Width	Reset Value	Description
CTRL	0x000	Read/Write	4	0x0	• [3]: System timer interrupt enable • [2]: Select external input as clock • [1]: Select external input as enable • [0]: Enable
VALUE	0x004	Read/Write	32	0x00000000	Current value
RELOAD	0x008	Read/Write	32	0x00000000	Reload value. Write to this register to set the current value.
INTSTATUS/ INTCLEAR	0x00C	Read/Write	1	0x0	[0]: Timer interrupt. Write one to clear.
PID4	0XFD0	Read only	8	0x04	Peripheral ID Register 4
PID5	0XFD4	Read only	8	0x00	Peripheral ID Register 5
PID6	0XFD8	Read only	8	0x00	Peripheral ID Register 6
PID7	0XFDC	Read only	8	0x00	Peripheral ID Register 7
PID0	0XFE0	Read only	8	0x22	Peripheral ID Register 0
PID1	0XFE4	Read only	8	0XB8	Peripheral ID Register 1
PID2	0XFE8	Read only	8	0X1B	Peripheral ID Register 2
PID3	0XFEC	Read only	8	0X00	Peripheral ID Register 3
CID0	0XFF0	Read only	8	0X0D	Component ID Register 0
CID1	0XFF4	Read only	8	0XF0	Component ID Register 1
CID2	0XFF8	Read only	8	0X05	Component ID Register 2
CID3	0XFFC	Read only	8	0XB1	Component ID Register 3

2.7.8 UART

The GW1NS-4C embedded microprocessor system contains two UART: UART0 and UART1. These can be accessed and controlled through APB1 bus, it supports Max. baud rate of 921.6Kbits/s.

UART0 and UART1 support 8 bits communication without parity and one stop bit.

Figure 2-18 APB UART Buffering
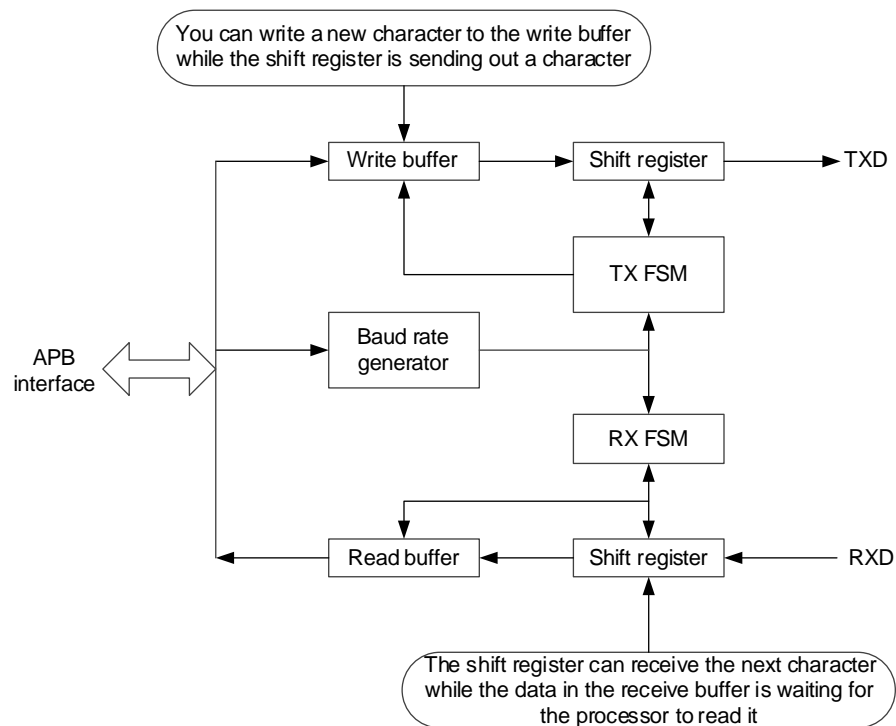
UART0 and UART support a high-speed test mode. When CTRL [6] is set to 1, the serial data is transmitted at one bit per clock cycle. This enables you to send text messages in a much shorter simulation time. The APB interface always sends an "OK" response with no wait state. You must program the baud rate divider register BAUDDIV before enabling the UART.

The BAUDTICK output pulses at a frequency of 16 times that of the programmed baud rate. You can use this external signal for capturing UART data in a synchronous environment. The TXEN output signal indicates the status of CTRL [0]. You can use this signal to switch a bidirectional I/O pin in a silicon device to UART data output mode automatically when the UART transmission feature is enabled.

The buffer overrun status in the STATE field is used to drive the overrun interrupt signals. Therefore, clearing the buffer overrun status de-asserts the overrun interrupt, and clearing the overrun interrupt bit also clears the buffer overrun status bit in the STATE field.

See Table 2-11 for the UART Register Description. The UART0 base address is 0x40004000, and the UART1 base address is 0x40005000.

Table 2-11 UART0/UART1 Register

Name	Base Offset	Type	Data Width	Reset Value	Description
DATA	0x000	Read/Write	8	0x--	8 bits data Read: Received data. Write: Transmit data.
STATE	0x004	Read/Write	4	0x0	[3]: RX buffer overrun, write 1 to clear. [2]: TX buffer overrun, write 1 to clear. [1]: RX buffer full, read-only. [0]: TX buffer full, read-only.
CTRL	0x008	Read/Write	7	0x00	[6]：High-speed test mode for TX only. [5]：RX overrun interrupt enable. [4]：TX overrun interrupt enable. [3]：RX interrupt enable. [2]：TX interrupt enable. [1]：RX enable. [0]：TX enable.
INTSTATUS/ INTCLEAR	0x00C	Read/Write	4	0x0	[3]：RX overrun interrupt, write 1 to clear. [2]：TX overrun interrupt, write 1 to clear. [1]：RX interrupt, write 1 to clear. [0]：TX interrupt, write 1 to clear.
BAUDDIV	0x010	Read/Write	20	0x00000	[19:0]: Baud rate divider. The minimum number is 16.
PID4	0XFD0	Read only	8	0x04	Peripheral ID Register 4
PID5	0XFD4	Read only	8	0x00	Peripheral ID Register 5
PID6	0XFD8	Read only	8	0x00	Peripheral ID Register 6
PID7	0XFDC	Read only	8	0x00	Peripheral ID Register 7
PID0	0XFE0	Read only	8	0x21	Peripheral ID Register 0
PID1	0XFE4	Read only	8	0XB8	Peripheral ID Register 1
PID2	0XFE8	Read only	8	0X1B	Peripheral ID Register 2
PID3	0XFEC	Read only	8	0X00	Peripheral ID Register 3
CID0	0XFF0	Read only	8	0X0D	Component ID Register 0
CID1	0XFF4	Read only	8	0XF0	Component ID Register 1
CID2	0XFF8	Read only	8	0X05	Component ID Register 2
CID3	0XFFC	Read only	8	0XB1	Component ID Register 3

2.7.9 Watchdog

The GW1NS-4C embedded microprocessor system contains one watchdog module. This can be accessed and controlled through the APB1 bus.

The APB watchdog module is based on a 32 bits down-counter that is initialized from the reload register, WDOGLOAD.

The watchdog module generates a regular interrupt, WDOGINT, depending on a programmed value. The counter decrements by one on each positive clock edge of WDOGCLK when the clock enable, WDOGCLKEN, is HIGH. The watchdog monitors the interrupt and asserts a reset request WDOGRES signal when the counter reaches 0, and the counter is stopped. On the next enabled WDOGCLK clock edge, the counter is reloaded from the WDOGLOAD register and the countdown sequence continues.

The watchdog module applies a reset to a system in the event of a software failure, providing a way to recover from software crashes. For example, if the interrupt is not cleared by the time the counter next reaches 0, the watchdog module initiates the reset signal.

Figure 2-19 below depicts the watchdog operation.

Figure 2-19 Watchdog Operation
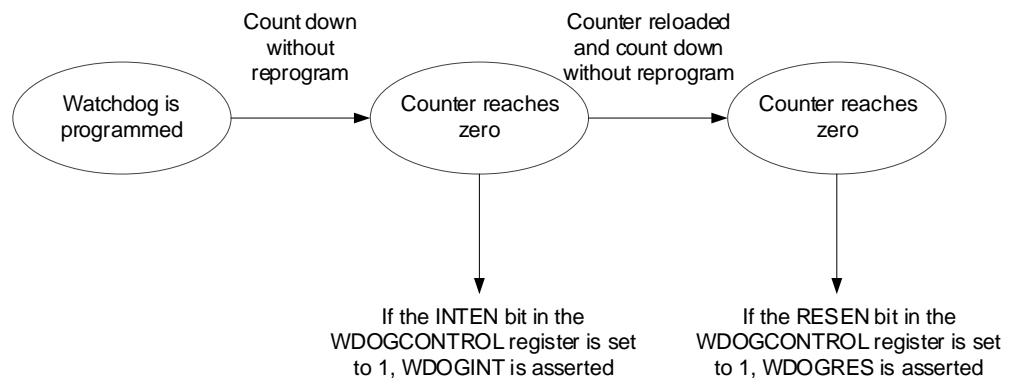
The watchdog register is as shown in Table 2-12. The watchdog base address is 0x40008000.

Table 2-12 Watchdog Register

Name	Base Offset	Type	Data Width	Reset Value	Description
WDOGLOAD	0x00	Read/ Write	32	0xFFFFFFFF	Watchdog Load Register
WDOGVALUE	0x04	Read only	32	0xFFFFFFFF	Watchdog Value Register
WDOGCONTROL	0x08	Read/ Write	2	0x0	Watchdog Control Register [1]： [0]：
WDOGINTCLR	0x0C	Write only	-	0x-	Watchdog Clear Interrupt Register
WDOGRIS	0x10	Read only	1	0x0	Watchdog Raw Interrupt Status Register
WDOGMIS	0x14	Read only	1	0x0	Watchdog Interrupt Status Register
WDOGLOCK	0xC00	Read/ Write	32	0x0	Watchdog Lock Register
WDOGTCR	0xF00	Read/ Write	1	0x0	Watchdog Integration Test Control Register
WDOGTOP	0xF04	Write only	2	0x0	Watchdog Integration Test Output Set Register
WDOGPERIPHID4	0XFD0	Read only	8	0x04	Peripheral ID Register 4
WDOGPERIPHID5	0XFD4	Read only	8	0x00	Peripheral ID Register 5
WDOGPERIPHID6	0XFD8	Read only	8	0x00	Peripheral ID Register 6
WDOGPERIPHID7	0XFDC	Read only	8	0x00	Peripheral ID Register 7
WDOGPERIPHID0	0XFE0	Read only	8	0x24	Peripheral ID Register 0
WDOGPERIPHID1	0XFE4	Read only	8	0XB8	Peripheral ID Register 1
WDOGPERIPHID2	0XFE8	Read only	8	0X1B	Peripheral ID Register 2
WDOGPERIPHID3	0XFEC	Read only	8	0X00	Peripheral ID Register 3
WDOGPCELLID0	0XFF0	Read only	8	0X0D	Component ID Register 0
WDOGPCELLID1	0XFF4	Read only	8	0XF0	Component ID Register 1
WDOGPCELLID2	0XFF8	Read only	8	0X05	Component ID Register 2
WDOGPCELLID3	0XFFC	Read only	8	0XB1	Component ID Register 3

2.7.10 GPIO

The GW1NS-4C microprocessor system communicates with the GPIO block through the AHB bus. The GIPO block interconnects with the FPGA. GPIO provides a 16 bits I/O interface with the following properties:

● Programmable interrupt generation capability. You can configure each bit of the I/O pins to generate interrupts;
● Bit masking support using address values;
● Registers for alternate function switching with pin multiplexing support;
● Thread safe operation by providing separate set and clear addresses for control registers.

The GPIO register is as shown in Table 2-13. The GPIO base address is 0 x 40010000.

Table 2-13 GPIO Register

Name	Base Offset	Type	Data Width	Reset Value	Description
DATA	0x0000	Read/Write	16	0x----	Data value [15:0]
DATAOUT	0x0004	Read/Write	16	0x0000	Data output register value [15:0]
OUTENSET	0x0010	Read/Write	16	0x0000	Output enable set [15:0] Write 1: Set the output enable bit. Write 0: No effect. Read 1: Indicates the signal direction as output. Read 0: Indicates the signal direction as input.
OUTENCLR	0x0014	Read/Write	16	0x0000	Output enable clear [15:0]
ALTFUNCSET	0x0018	Read/Write	16	0x0000	Alternative function set [15:0] Write 1: Sets the ALTFUNC bit. Write 0: No effect. Read 0: GPIO as I/O Read 1: ALTFUNC Function
ALTFUNCCLR	0x001C	Read/Write	16	0x0000	Alternative function clear [15:0]
INTENSET	0x0020	Read/Write	16	0x0000	Interrupt enable set [15:0] Write 1: Sets the enable bit. Write 0: No effect. Read 0: Interrupt disabled. Read 1: Interrupt enabled.
INTENCLR	0x0024	Read/Write	16	0x0000	Interrupt enable clear [15:0] Write 1: Clear the enable bit. Write 0: No effect. Read 0: Interrupt disabled. Read 1: Interrupt enabled.
INTTYPESET	0x0028	Read/Write	16	0x0000	Interrupt type set [15:0]
INTTYPECLR	0x002C	Read/Write	16	0x0000	Interrupt type clear [15:0]
INTPOLSET	0x0030	Read/Write	16	0x0000	Polarity-level, edge interrupt request configuration [15:0]

Name	Base Offset	Type	Data Width	Reset Value	Description
INTPOLCLR	0x0034	Read/Write	16	0x0000	Polarity-level, edge interrupt request configuration [15:0]
INTSTATUS/ INTCLEAR	0x0038	Read/Write	16	0x0000	Read interrupt status register Write 1: Clear the interrupt request
MASKLOWBYTE	0x0400-0x07FC	Read/Write	16	0x0000	–
MASKHIGHBYTE	0x0800-0x0BFC	Read/Write	16	0x0000	–
Reserved	0x0C00-0x0FCF	–	–	–	Reserved
PID4	0XFD0	Read only	8	0x04	Peripheral ID Register 4
PID5	0XFD4	Read only	8	0x00	Peripheral ID Register 5
PID6	0XFD8	Read only	8	0x00	Peripheral ID Register 6
PID7	0XFDC	Read only	8	0x00	Peripheral ID Register 7
PID0	0XFE0	Read only	8	0x20	Peripheral ID Register 0
PID1	0XFE4	Read only	8	0XB8	Peripheral ID Register 1
PID2	0XFE8	Read only	8	0X1B	Peripheral ID Register 2
PID3	0XFEC	Read only	8	0X00	Peripheral ID Register 3
CID0	0XFF0	Read only	8	0X0D	Component ID Register 0
CID1	0XFF4	Read only	8	0XF0	Component ID Register 1
CID2	0XFF8	Read only	8	0X05	Component ID Register 2
CID3	0XFFC	Read only	8	0XB1	Component ID Register 3

2.7.11 Debug Access Port

The Cortex-M3 processor block contains a DAP that consist of a JTAG DAP and a TPIU port. Both interface to the FPGA Fabric. The JTAG-DAP is based on the IEEE1149.1 Joint Test Action Group Boundary-Scan Standard.

JTAG-DP functions consist of the following three parts:

- JTAG-DP sate machine
- Instruction register (IR) and the related IR scan chain, which are used to control JTAG and the current register actions
- DR register and the related DR scan chain, which connect with the JTAG-DP register.

2.7.12 Memory Mapping

Figure 2-20 Memory Mapping
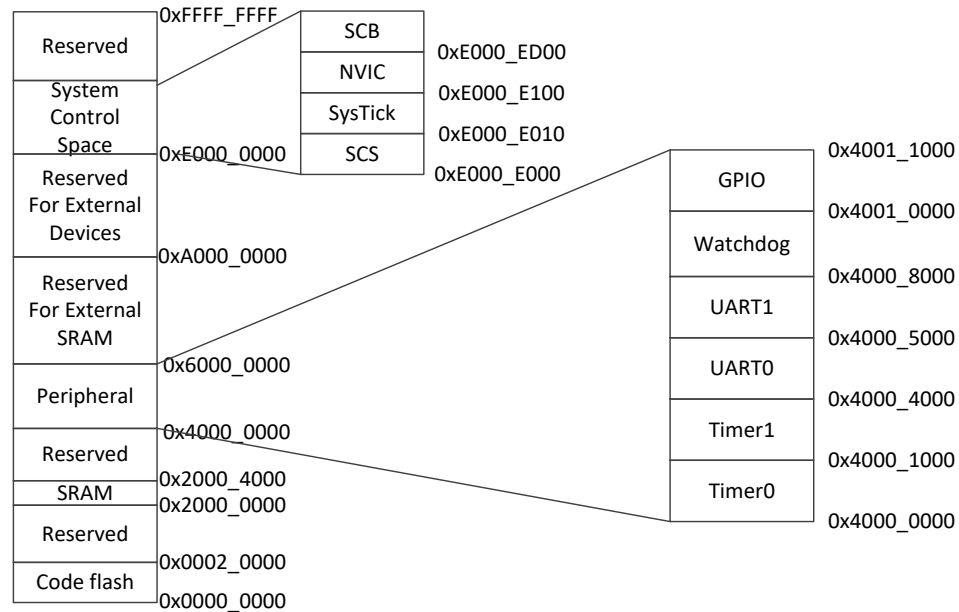
2.7.13 Application

The "Cortex-M3" IP can be called in Gowin software. For further detailed information, please refer to IPUG931, Gowin_EMPU (GW1NS-4C) Hardware Design Reference Manual.

2.8 Clocks

The clock resources and wiring are critical for high-performance applications in FPGA. The GW1NS series of FPGA products provide global clocks (GCLKs) which connect to all the registers directly. In addition, high-speed clocks (HCLKs), PLLs, etc. are provided.

See UG286, Gowin Clock User Guide for more information.

2.8.1 Global Clocks

The Global Clock(GCLK) resources are distributed as quadrants in the GW1NS devices, with each quadrant providing eight GCLKs. The clock sources of GCLKs include dedicated clock input pins and CRUs, and better clock performance can be achieved by using the dedicated clock input pins.

2.8.2 PLLs

The PLL (Phase-locked Loop) is one kind of feedback control circuit. The frequency and phase of the internal oscillator signal are controlled by the external input reference clock.

PLLs in the GW1NS series of FPGA products can provide synthesizable clock frequencies. Frequency adjustment (multiplication and division), phase adjustment, and duty cycle adjustment can be achieved by configuring the parameters.

2.8.3 High-speed Clocks

The high-speed clocks (HCLKs) are designed to facilitate high-performance I/O data transmission and are specifically tailored for source synchronous data transmission protocols. GW1NS-4C/4 devices have two HCLKs on each side, see Figure 2-21.

Figure 2-21 GW1NS-4C/4 HCLK Distribution
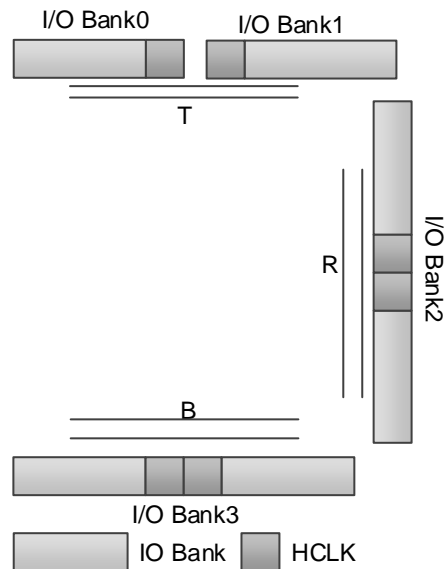
2.9 Long Wires

As a supplement to the CRU, the GW1NS series of FPGA products provide another kind of routing resource - the long wire, which can be used for clock, clock enable, set/reset, or other high fan out signals.

2.10 Global Set/Reset

The GW1NS series of FPGA products offer a dedicated global set/reset (GSR) network that connects directly to the device's internal logic and can be used as asynchronous/synchronous set or asynchronous/synchronous reset, with the registers in the CLUs and I/Os being able to be configured independently.

2.11 Programming & Configuration

The GW1NS series of FPGA products support SRAM configuration and Flash programming. Flash programming includes on-chip Flash programming and off-chip Flash programming.

Besides JTAG, the GW1NS series of FPGA products also support Gowin's own GowinCONFIG configuration mode: AUTO BOOT, SSPI, MSPI, DUAL BOOT, SERIAL, and CPU. All the devices support JTAG mode and AUTO BOOT mode.

2.11.1 SRAM Configuration

If SRAM configuration is used, the configuration data needs to be re-downloaded upon each power-up.

2.11.2 Flash programming

The Flash programming data is stored in the on-chip Flash. Each time the device is powered up, the configuration data is transferred from the Flash to the SRAM. Configuration can be completed within a few milliseconds after power-up, which is also known as "instant on". In addition, the GW1NS series of FPGA products support off-chip Flash programming and DUAL BOOT. For more information, please refer to UG290, Gowin FPGA Products Programming and Configuration User Guide.

The GW1NS series of FPGA products support the feature of background upgrade. That is to say, you can program the on-chip Flash or off-chip Flash via the JTAG[1] interface without affecting the current working state. During programming, the device works according to the previous configuration. After the programming is done, you can trigger RECONFIG_N with a low level to complete the upgrade. This feature is suitable for the applications requiring long online time and irregular upgrades.

Note!

- [1] For the GW1NS-4C device, the JTAG background upgrade feature is not available if its embedded Cortex-M3 is used.

- [2] As a configuration pin, RECONFIG_N is an input pin with internal weak pull-up, but as a GPIO, RECONFIG_N can only be used for output. For more information, please refer to *UG290, Gowin FPGA Products Programming and Configuration User Guide*.

2.12 On-chip Oscillator

The GW1NS series of FPGA products have an embedded programmable on-chip clock oscillator which provides a clock source for the MSPI configuration mode with a tolerance of ±5%.

The on-chip oscillator of the GW1NS-4C/4 device supports user-configurable power saving mode.

The on-chip oscillator also provides a clock resource for user designs. Up to 64 clock frequencies can be obtained by setting the parameters.

The following formula is used to get the output clock frequency of the on-chip oscillator of GW1NS-4C/4:

$$f_{out}=210MHz/Param$$

Note!

"Param" should be even numbers from 2 to 128.

Table 2-14 lists some frequencies provided by the on-chip oscillator.

Table 2-14 Output Frequency Options of the On-chip Oscillator of GW1NS-4C/4

Mode[3]	Frequency	Mode	Frequency	Mode	Frequency
0	2.5MHz[1]	8	7.8MHz	16	15.6MHz
1	5.4MHz	9	8.3MHz	17	17.9MHz
2	5.7MHz	10	8.9MHz	18	21MHz
3	6.0MHz	11	9.6MHz	19	25MHz
4	6.3MHz	12	10.4MHz	20	31.3MHz
5	6.6MHz	13	11.4MHz	21	41.7MHz
6	6.9MHz	14	12.5MHz	22	62.5MHz
7	7.4MHz	15	13.9MHz	23	125MHz[2]

Note!

- [1] Default frequency.
- [2] This is not available for the MSPI configuration mode.
- [3] "mode" here is only a label, not a parameter.

3 DC and Switching Characteristics

Note!

Please ensure that you use Gowin's devices within the recommended operating conditions and ranges. Data beyond the working conditions and ranges are for reference only. Gowin does not guarantee that all devices will operate normally beyond the operating conditions and ranges.

3.1 Operating Conditions

3.1.1 Absolute Max. Ratings

Table 3-1 Absolute Max. Ratings

Name	Description	Min.	Max.
V_{CC}	Core voltage	-0.5V	1.32V
V_{CCIOx}	I/O Bank voltage	-0.5V	3.75V
V_{CCX}	Auxiliary voltage(LV version)	-0.5V	3.75V
-	I/O voltage applied[1]	-0.5V	3.75V
Storage Temperature	Storage temperature	-65℃	+150℃
Junction Temperature	Junction temperature	-40℃	+125℃

Note!

● [1] Overshoot and undershoot of -2V to (V_{IHMAX} + 2)V are allowed for a duration of <20 ns.

3.1.2 Recommended Operating Conditions

Table 3-2 Recommended Operating Conditions

Name	Description	Min.	Max.
V_{CC}	Core voltage	1.14V	1.26V
V_{CCIOx}	I/O Bank voltage (LV version)	1.14V	3.6V
V_{CCX}	Auxiliary voltage (LV version)	1.71V	3.6V
T_{JCOM}	Junction temperature (commercial operation)	0℃	+85℃
T_{JIND}	Junction temperature (industrial operation)	-40℃	+100℃

Note!

- For more information on the power supplies, please refer to UG824, GW1NS-4&4C Pinout.

- The allowable ripples on V_{CC}, V_{CCIO}, and V_{CCX} are 3%, 5%, and 5% respectively. For devices of which the PLL is powered directly with V_{CC}, the ripple on V_{CC} can affect the jitter characteristics of the PLL output clock; 2). The ripple on V_{CCIO} can eventually be passed on to the output waveform of the IO Buffer.

3.1.3 Power Supply Ramp Rates

Table 3-3 Power Supply Ramp Rates

Name	Description	Min.	Typ.	Max.
V_{CC} Ramp	Power supply ramp rates for V_{CC}	0.6mV/µs	-	6mV/µs
V_{CCX} Ramp	Power supply ramp rates for V_{CCX}	0.6mV/µs	-	10mV/µs
V_{CCIO} Ramp	Power supply ramp rates for V_{CCIO}	0.1mV/µs	-	10mV/µs

Note!

- A monotonic ramp is required for all power supplies.

- All power supplies need to be in the operating range as defined in Table 3-2 before configuration. Power supplies that are not in the operating range need to be adjusted to a faster ramp rate, or you have to delay configuration.

3.1.4 Hot Socketing Specifications

Table 3-4 Hot Socketing Specifications

Name	Description	Condition	I/O Type	Max.
I_{HS}	Input or I/O leakage current	$0<V_{IN}<V_{IH}(MAX)$	I/O	150uA
I_{HS}	Input or I/O leakage current	$0<V_{IN}<V_{IH}(MAX)$	TDI,TDO, TMS,TCK	120uA

3.1.5 POR Specifications

Table 3-5 POR Parameters

Name	Description	Device	Name	Value
V_{POR_UP}	Power on reset ramp up trip point	GW1NS-4	V_{CC}	0.95V
			V_{CCX}	1.5V
			V_{CCIO}	0.95V
		GW1NS-4C	V_{CC}	TBD
			V_{CCX}	TBD
			V_{CCIO}	TBD
V_{POR_DOWN}	Power on reset ramp down trip point	GW1NS-4	V_{CC}	0.75V
			V_{CCX}	1.25V
			V_{CCIO}	0.7V
		GW1NS-4C	V_{CC}	TBD
			V_{CCX}	TBD
			V_{CCIO}	TBD

3.2 ESD performance

Table 3-6 GW1NS ESD - HBM

Device	GW1NS-4C	GW1NS-4
QN48	HBM>1,000V	HBM>1,000V
CS49	HBM>1,000V	HBM>1,000V
MG64	HBM>1,000V	HBM>1,000V
QN32	-	HBM>1,000V

Table 3-7 GW1NS ESD - CDM

Device	GW1NS-4C	GW1NS-4
QN48	CDM>500V	CDM>500V
CS49	CDM>500V	CDM>500V
MG64	CDM>500V	CDM>500V
QN32	-	CDM>500V

3.3 DC Characteristics

3.3.1 DC Electrical Characteristics over Recommended Operating Conditions

Table 3-8 DC Electrical Characteristics over Recommended Operating Conditions

Name	Description	Condition	Min.	Typ.	Max.
I_{IL}, I_{IH}	Input or I/O leakage current	$V_{CCIO}<V_{IN}<V_{IH}(MAX)$	-	-	210µA
		$0<V_{IN}<V_{CCIO}$	-	-	10µA
I_{PU}	I/O Active Pull-up Current	$0<V_{IN}<0.7V_{CCIO}$	-30µA	-	-150µA
I_{PD}	I/O Active Pull-down Current	$V_{IL}(MAX)<V_{IN}<V_{CCIO}$	30µA	-	150µA
I_{BHLS}	Bus Hold Low Sustaining Current	$V_{IN}=V_{IL}(MAX)$	30µA	-	-
I_{BHHS}	Bus Hold High Sustaining Current	$V_{IN}=0.7V_{CCIO}$	-30µA	-	-
I_{BHLO}	Bus Hold Low Overdrive Current	$0 \leqslant V_{IN} \leqslant V_{CCIO}$	-	-	150µA
I_{BHHO}	Bus Hold High Overdrive Current	$0 \leqslant V_{IN} \leqslant V_{CCIO}$	-	-	-150µA
V_{BHT}	Bus Hold Trip Points		$V_{IL}(MAX)$	-	$V_{IH}(MIN)$
C1	I/O Capacitance			5pF	8pF
V_{HYST}	Hysteresis for Schmitt Trigger inputs	$V_{CCIO}=3.3V$, Hysteresis=L2H[1]	-	200mV	-
		$V_{CCIO}=2.5V$, Hysteresis= L2H	-	125mV	-
		$V_{CCIO}=1.8V$, Hysteresis= L2H	-	60mV	-
		$V_{CCIO}=1.5V$, Hysteresis= L2H	-	40mV	-
		$V_{CCIO}=1.2V$, Hysteresis= L2H	-	20mV	-
		$V_{CCIO}=3.3V$, Hysteresis= H2L[1]	-	200mV	-
		$V_{CCIO}=2.5V$, Hysteresis= H2L	-	125mV	-
		$V_{CCIO}=1.8V$, Hysteresis= H2L	-	60mV	-
		$V_{CCIO}=1.5V$, Hysteresis= H2L	-	40mV	-
		$V_{CCIO}=1.2V$, Hysteresis= H2L	-	20mV	-
		$V_{CCIO}=3.3V$, Hysteresis= HIGH[1],[2]	-	400mV	-
		$V_{CCIO}=2.5V$, Hysteresis= HIGH	-	250mV	-
		$V_{CCIO}=1.8V$, Hysteresis= HIGH	-	120mV	-
		$V_{CCIO}=1.5V$, Hysteresis= HIGH	-	80mV	-
		$V_{CCIO}=1.2V$, Hysteresis= HIGH	-	40mV	-

Note!

- [1] Hysteresis="NONE", "L2H", "H2L", "HIGH" indicates the Hysteresis options that can be set when setting I/O Constraints in the FloorPlanner tool of Gowin EDA, for more details, see SUG935, Gowin Design Physical Constraints User Guide.

- [2] Enabling the L2H (low to high) option means raising V_{IH} by V_{HYST}; enabling the H2L (high to low) option means lowering V_{IL} by V_{HYST}; enabling the HIGH option means enabling both L2H and H2L options, i.e. $V_{HYST}(HIGH) = V_{HYST}(L2H) + V_{HYST}(H2L)$. The diagram is shown below.
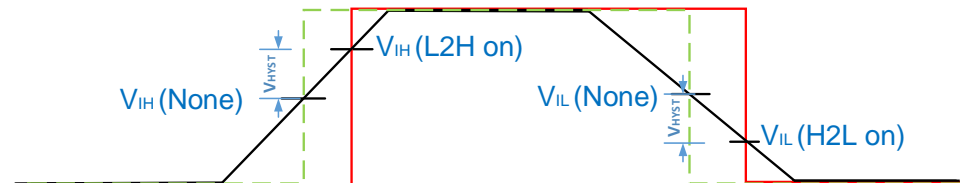
3.3.2 Static Current

Table 3-9 Static Current

Name	Description	Device type	Device	Typ.
I_{CC}	V_{CC} current (V_{CC}=1.2V)	LV version	GW1NS-4	2.8mA
I_{CCX}	V_{CCX} current (V_{CCX}=2.5V)	LV version	GW1NS-4	1.2mA
I_{CCIO}	V_{CCIO} current (V_{CCIO}=2.5V)	LV version	GW1NS-4	0.7mA

Note!

- Test conditions: room temperature, speed grade C6/I5.

3.3.3 Recommended I/O Operating Conditions

Table 3-10 Recommended I/O Operating Conditions

Name	V_{CCIO} (V) for Output			V_{REF} (V) for Input		
	Min.	Typ.	Max.	Min.	Typ.	Max.
LVTTL33	3.135	3.3	3.6	-	-	-
LVCMOS33	3.135	3.3	3.6	-	-	-
LVCMOS25	2.375	2.5	2.625	-	-	-
LVCMOS18	1.71	1.8	1.89	-	-	-
LVCMOS15	1.425	1.5	1.575	-	-	-
LVCMOS12	1.14	1.2	1.26	-	-	-
SSTL15	1.425	1.5	1.575	0.68	0.75	0.9
SSTL18_I	1.71	1.8	1.89	0.833	0.9	0.969
SSTL18_II	1.71	1.8	1.89	0.833	0.9	0.969
SSTL25_I	2.375	2.5	2.645	1.15	1.25	1.35
SSTL25_II	2.375	2.5	2.645	1.15	1.25	1.35
SSTL33_I	3.135	3.3	3.6	1.3	1.5	1.7
SSTL33_II	3.135	3.3	3.6	1.3	1.5	1.7
HSTL18_I	1.71	1.8	1.89	0.816	0.9	1.08
HSTL18_II	1.71	1.8	1.89	0.816	0.9	1.08

Name	V$_{CCIO}$ (V) for Output			V$_{REF}$ (V) for Input		
	Min.	Typ.	Max.	Min.	Typ.	Max.
HSTL15	1.425	1.5	1.575	0.68	0.75	0.9
PCI33	3.135	3.3	3.6	-	-	-
LVPECL33E	3.135	3.3	3.6	-	-	-
MLVDS25E	2.375	2.5	2.625	-	-	-
BLVDS25E	2.375	2.5	2.625	-	-	-
RSDS25E	2.375	2.5	2.625	-	-	-
LVDS25E	2.375	2.5	2.625	-	-	-
SSTL15D	1.425	1.5	1.575	-	-	-
SSTL18D_I	1.71	1.8	1.89	-	-	-
SSTL18D_II	1.71	1.8	1.89	-	-	-
SSTL25D_I	2.375	2.5	2.625	-	-	-
SSTL25D_II	2.375	2.5	2.625	-	-	-
SSTL33D_I	3.135	3.3	3.6	-	-	-
SSTL33D_II	3.135	3.3	3.6	-	-	-
HSTL15D	1.425	1.575	1.89	-	-	-
HSTL18D_I	1.71	1.8	1.89	-	-	-
HSTL18D_II	1.71	1.8	1.89	-	-	-

3.3.4 Single-ended I/O DC Characteristics

Table 3-11 Single-ended I/O DC Characteristics

Name	V_{IL}		V_{IH}		V_{OL} (Max)	V_{OH} (Min)	I_{OL}[1] (mA)	I_{OH}[1] (mA)
	Min	Max	Min	Max				
LVCMOS33 LVTTL33	-0.3V	0.8V	2.0V	3.6V	0.4V	V_{CCIO}-0.4V	4	-4
							8	-8
							12	-12
							16	-16
							24	-24
					0.2V	V_{CCIO}-0.2V	0.1	-0.1
LVCMOS25	-0.3V	0.7V	1.7V	3.6V	0.4V	V_{CCIO}-0.4V	4	-4
							8	-8
							12	-12
							16	-16
					0.2V	V_{CCIO}-0.2V	0.1	-0.1
LVCMOS18	-0.3V	0.35*V_{CCIO}	0.65*V_{CCIO}	3.6V	0.4V	V_{CCIO}-0.4V	4	-4
							8	-8
							12	-12
					0.2V	V_{CCIO}-0.2V	0.1	-0.1
LVCMOS15	-0.3V	0.35*V_{CCIO}	0.65*V_{CCIO}	3.6V	0.4V	V_{CCIO}-0.4V	4	-4
							8	-8
					0.2V	V_{CCIO}-0.2V	0.1	-0.1
LVCMOS12	-0.3V	0.35*V_{CCIO}	0.65*V_{CCIO}	3.6V	0.4V	V_{CCIO}-0.4V	4	-4
							8	-8
					0.2V	V_{CCIO}-0.2V	0.1	-0.1
PCI33	-0.3V	0.3*V_{CCIO}	0.5*V_{CCIO}	3.6V	0.1*V_{CCIO}	0.9*V_{CCIO}	1.5	-0.5
SSTL33_I	-0.3V	V_{REF}-0.2V	V_{REF}+0.2V	3.6V	0.7	V_{CCIO}-1.1V	8	-8
SSTL25_I	-0.3V	V_{REF}-0.18V	V_{REF}+0.18V	3.6V	0.54V	V_{CCIO}-0.62V	8	-8
SSTL25_II	-0.3V	V_{REF}-0.18V	V_{REF}+0.18V	3.6V	NA	NA	NA	NA
SSTL18_II	-0.3V	V_{REF}-0.125V	V_{REF}+0.125V	3.6V	NA	NA	NA	NA
SSTL18_I	-0.3V	V_{REF}-0.125V	V_{REF}+0.125V	3.6V	0.40V	V_{CCIO}-0.40V	8	-8
SSTL15	-0.3V	V_{REF}-0.1V	V_{REF}+ 0.1V	3.6V	0.40V	V_{CCIO}-0.40V	8	-8
HSTL18_I	-0.3V	V_{REF}-0.1V	V_{REF}+ 0.1V	3.6V	0.40V	V_{CCIO}-0.40V	8	-8
HSTL18_II	-0.3V	V_{REF}-0.1V	V_{REF}+ 0.1V	3.6V	NA	NA	NA	NA
HSTL15_I	-0.3V	V_{REF}-0.1V	V_{REF}+ 0.1V	3.6V	0.40V	V_{CCIO}-0.40V	8	-8
HSTL15_II	-0.3V	V_{REF}-0.1V	V_{REF}+ 0.1V	3.6V	NA	NA	NA	NA

Note!

[1] The total DC current limit(sourced and sunk current) of all IOs in the same bank: the total DC current of all IOs in the same bank shall not be greater than n*8mA, where n represents the number of IOs bonded out from a bank.

3.3.5 Differential I/O DC Characteristics

Table 3-12 Differential I/O DC Characteristics

LVDS25

Name	Description	Test conditions	Min.	Typ.	Max.	Unit
V_{INA}, V_{INB}	Input Voltage		0	-	2.15	V
V_{CM}	Input Common Mode Voltage	Half the Sum of the Two Inputs	0.05	-	2.1	V
V_{THD}	Differential Input Threshold	Difference Between the Two Inputs	±100	-	±600	mV
I_{IN}	Input Current	Power On or Power Off	-	-	±20	µA
V_{OH}	Output High Voltage for V_{OP} or V_{OM}	$R_T = 100\Omega$	-	-	1.60	V
V_{OL}	Output Low Voltage for V_{OP} or V_{OM}	$R_T = 100\Omega$	0.9	-	-	V
V_{OD}	Output Voltage Differential	$(V_{OP} - V_{OM})$, $R_T=100\Omega$	250	350	450	mV
ΔV_{OD}	Change in V_{OD} Between High and Low		-	-	50	mV
V_{OS}	Output Voltage Offset	$(V_{OP} + V_{OM})/2$, $R_T=100\Omega$	1.125	1.20	1.375	V
ΔV_{OS}	Change in V_{OS} Between High and Low		-	-	50	mV
I_S	Short-circuit current	$V_{OD} = 0V$ outputs short-circuited	-	-	15	mA

3.4 Switching Characteristics

3.4.1 I/O Speed

Table 3-13 I/O Speed Parameters

Name	Description		Min	Max	Unit
f_{MAX_LVDS}	Max. LVDS frequency	GW1NS-4	-	750M	Hz

3.4.2 CFU Switching Characteristics

Table 3-14 CFU Timing Parameters

Name	Description	Speed Grade		Unit
		Min	Max	
t_{LUT4_CFU}	LUT4 delay	-	0.674	ns
t_{LUT5_CFU}	LUT5 delay	-	1.388	ns
t_{LUT6_CFU}	LUT6 delay	-	2.01	ns
t_{LUT7_CFU}	LUT7 delay	-	2.632	ns
t_{LUT8_CFU}	LUT8 delay	-	3.254	ns
t_{SR_CFU}	Set/Reset to Register output	-	1.86	ns
t_{CO_CFU}	Clock to Register output	-	0.76	ns

3.4.3 Clock and I/O Switching Characteristics

Table 3-15 External Switching Characteristics

Name	-5		-6		Unit
	Min	Max	Min	Max	
HCLK Tree delay	0.8	1.4	0.5	1.2	ns
PCLK Tree delay(GCLK0~5)	1.4	2.6	1.0	2.2	ns
PCLK Tree delay(GCLK6~7)	1.8	3.2	1.4	2.9	ns
Pin-LUT-Pin Delay	3.4	5	3	4.5	ns

3.4.4 Gearbox Switching Characteristics

Table 3-16 Gearbox Timing Parameters

Name	Description	Typ.	Unit
FMAX$_{IDDR}$	1:2 Gearbox maximum serial input rate	400	Mbps
FMAX$_{IDES4}$	1:4 Gearbox maximum serial input rate	800	Mbps
FMAX$_{IDES7}$	1:7 Gearbox maximum serial input rate	1000	Mbps
FMAX$_{IDESx}$	1:8/1:10/1:16 Gearbox maximum serial input rate	1100	Mbps
FMAX$_{ODDR}$	2:1 Gearbox maximum serial output rate	400	Mbps
FMAX$_{OSER4}$	4:1 Gearbox maximum serial output rate	800	Mbps
FMAX$_{OSER7}$	7:1 Gearbox maximum serial output rate	1000	Mbps
FMAX$_{OSERx}$	8:1/10:1/16:1 Gearbox maximum serial output rate	1100	Mbps

3.4.5 BSRAM Switching Characteristics

Table 3-17 BSRAM Timing Parameters

Name	Description	Speed Grade Min	Speed Grade Max	Unit
t$_{COAD\_BSRAM}$	Clock to output time of read address/data	-	5.10	ns
t$_{COOR\_BSRAM}$	Clock to output time of output register	-	0.56	ns

3.4.6 DSP Switching Characteristics

Table 3-18 DSP Timing Parameters

Name	Description	Speed Grade Min	Speed Grade Max	Unit
t$_{COIR\_DSP}$	Clock to output time of input register	-	4.80	ns
t$_{COPR\_DSP}$	Clock to output time of pipeline register	-	2.40	ns
t$_{COOR\_DSP}$	Clock to output time of output register	-	0.84	ns

3.4.7 On-chip Oscillator Switching Characteristics

Table 3-19 On-chip Oscillator Parameters

Name	Description		Min.	Typ.	Max.
f$_{MAX}$	On-chip Oscillator Output Frequency (0 ~ +85℃)	GW1NS-4	118.75MHz	125MHz	131.25MHz
	On-chip Oscillator Output Frequency (-40 ~ +100℃)	GW1NS-4	112.5MHz	125MHz	137.5MHz
t$_{DT}$	Output Clock Duty Cycle		43%	50%	57%
t$_{OPJIT}$	Output Clock Period Jitter		0.01UIPP	0.012UIPP	0.02UIPP

3.4.8 PLL Switching Characteristics

Table 3-20 PLL Parameters

Device	Speed Grade	Name	Min.	Max.
GW1NS-4/GW1NS-4C	C7/I6 C6/I5	CLKIN	3MHz	400MHz
		PFD	3MHz	400MHz
		VCO	400MHz	1200MHz
		CLKOUT	3.125MHz	600MHz
	C5/I4	CLKIN	3MHz	320MHz
		PFD	3MHz	320MHz
		VCO	320MHz	960MHz
		CLKOUT	2.5MHz	480MHz

3.5 Cortex-M3 AC/DC Characteristics

3.5.1 DC Characteristics

Table 3-21 Current Characteristics

Symbol	Description	Specification		Unit
		Min.	Max.	
I_{VCC}	Max. current of VCC	-	100	mA
I_{VSS}	Max. current of VSS	-	-100	mA
I_{INJ}	Leakage current	-	+/-5	mA

3.5.2 AC Characteristics

Table 3-22Clock Parameters

Symbol	Description	Device	Specification		Unit
			Min.	Max.	
f_{HCLK}	AHB clock frequency	GW1NS-4C	0	80	MHz
f_{PCLK}	APB clock frequency	GW1NS-4C	0	80	MHz

3.6 User Flash Characteristics(GW1NS-4)

3.6.1 DC Characteristics

Table 3-23 GW1NS-4 User Flash DC Characteristics[1], [4]

Name	Parameter	Max.		Unit	Wake-up time	Condition
		V_{CC}[3]	V_{CCX}			
Read mode(w/l 25ns)	I_{CC1}[2]	2.19	0.5	mA	NA	Minimum clock period, 100% duty cycle , VIN = "1/0"
Write mode		0.1	12	mA	NA	–
Erase mode		0.1	12	mA	NA	–
Page erase mode		0.1	12	mA	NA	–
Static read current (25-50ns)	I_{CC2}	980	25	µA	NA	XE=YE=SE="1", between T=T_{acc} and T=50ns, the I/O current is 0mA. After T=50ns, the internal timer turns off read mode, and the I/O current turns out to be the standby current.
Standby mode	I_{SB}	5.2	20	µA	0	V_{SS}, V_{CCX}, and V_{CC}

Note!

- [1] These values are average DC currents and the peak currents will be higher than these average currents.

- [2] I_{CC1} calculation in different cycle time of T_{new}.

  - T_{new}< T_{acc}: not allowed.
  - T_{new} = T_{acc} : see the table above.
  - T_{acc}<T_{new} - 50ns：I_{CC1} (new) = (I_{CC1} - I_{CC2})(T_{acc}/T_{new}) + I_{CC2}
  - T_{new}>50ns：I_{CC1} (new) = (I_{CC1} - I_{CC2})(T_{acc}/T_{new}) + 50ns*I_{CC2}/T_{new} + I_{SB}
  - t > 50ns：I_{CC2} = I_{SB}

- [3] V_{CC} must be greater than 1.08V from time zero of the wake-up time.

3.6.2 AC Characteristics

Table 3-24 GW1NS-4 User Flash Parameters[1], [4], [5]

User Mode	Parameter	Symbol	Min.	Max.	Unit
Access time	WC1	T_{acc}[2]	-	25	ns
	TC		-	22	ns
	BC		-	21	ns
	LT		-	21	ns
	WC		-	25	ns
Program/Erase to data storage setup time		T_{nvs}	5	-	µs
Data storage hold time		T_{nvh}	5	-	µs
Data storage hold time(mass erase)		T_{nvh1}	100	-	µs
Data storage to program setup time		T_{pgs}	10	-	µs
Program hold time		T_{pgh}	20	-	ns
Program time		T_{prog}	8	16	µs
Write prepare time		T_{wpr}	>0	-	ns
Write hold time		T_{whd}	>0	-	ns
Control to program/erase setup time		T_{cps}	-10	-	ns
SE to read control setup time		T_{as}	0.1	-	ns
Positive pulse width of SE		T_{pws}	5	-	ns
Address/data setup time		T_{ads}	20	-	ns
Address/data hold time		T_{adh}	20	-	ns
Data hold time		T_{dh}	0.5	-	ns
Address hold time in read mode	WC1	T_{ah}	25	-	ns
	TC		-	22	-	ns
	BC		-	21	-	ns
	LT		-	21	-	ns
	WC		-	25	-	ns
Negative pulse width of SE		T_{nws}	2	-	ns
Recovery time		T_{rcv}	10	-	µs
Data storage time		T_{hv}[3]	-	6	ms
Erase time		T_{erase}	100	120	ms
Mass erase time		T_{me}	100	120	ms
Wake-up time of power-down to standby		T_{wk_pd}	7	-	µs
Standby hold time		T_{sbh}	100	-	ns
V_{CC} setup time		T_{ps}	0	-	ns
V_{CCX} hold time		T_{ph}	0	-	ns

Note!

● [1] The values are simulation data and are subject to change.

- [2] After XADR, YADR, XE, and YE are valid, T_{acc} starts at the rising edge of SE. DOUT will be kept before the next valid read operation starts.

- [3] T_{hv} is the cumulative time from the start of the write operation to the next data erase operation. The same address cannot be written twice before the next erase; the same memory cell cannot be written twice before the next erase. This limitation is for security reasons.

- [4] All waveforms have a 1ns rising time and a 1ns falling time.

- [5] Control signals(X, YADR, XE, and YE) need to be held for at least T_{acc}, which starts at the rising edge of SE.

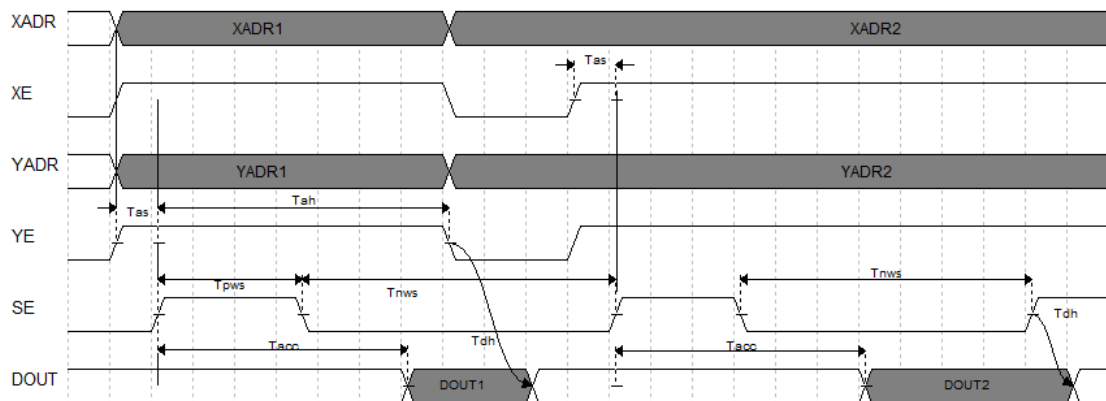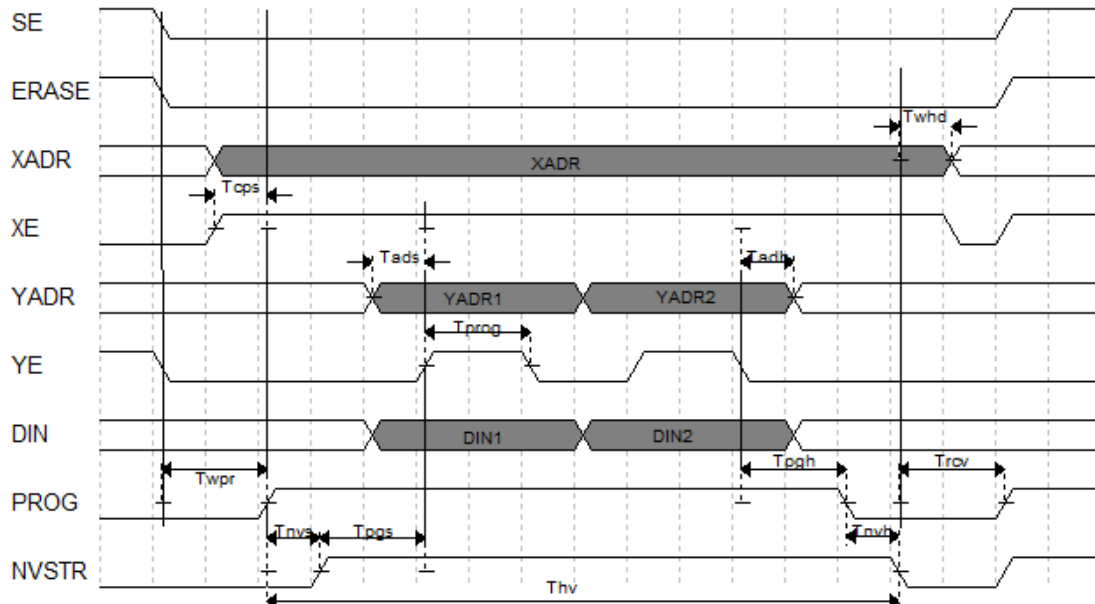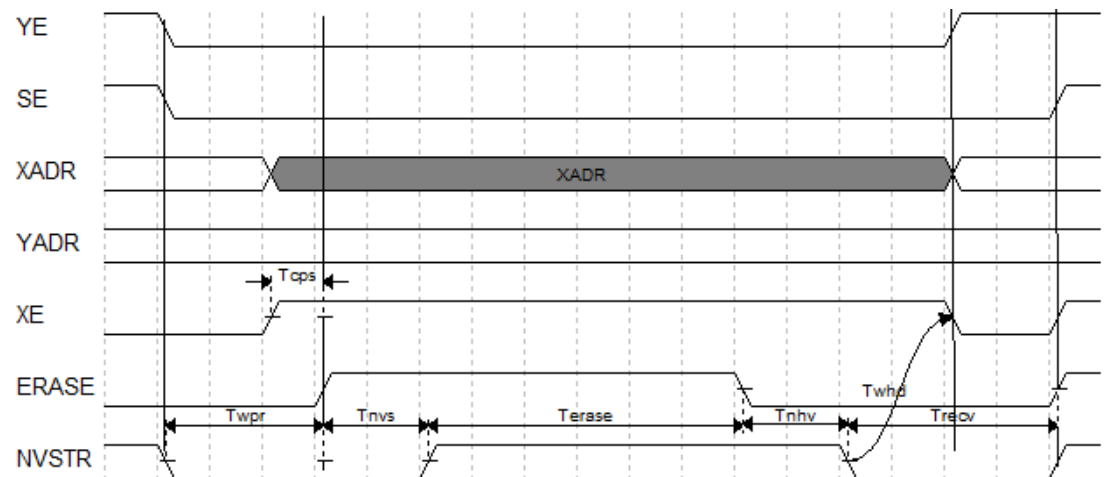## 3.6.3 Timing Diagrams

Figure 3-1 Read Timing

Figure 3-2 Program Timing

Figure 3-3 Erase Timing

3.7 Configuration Interface Timing Specification

The GW1NS series of FPGA products support six GowinCONFIG modes: AUTO BOOT, DUAL BOOT, SSPI, MSPI, SERIAL, and CPU. For more information, please refer to UG290, Gowin FPGA Products Programming and Configuration User Guide.

4 Ordering Information

4.1 Part Naming

Note!

- For more information about the packages, please refer to 1.2 Product Resources and 1.3 Package Information.

- The LittleBee family devices and Arora family devices of the same speed grade have different speeds.

- Both "C" and "I" are used in Gowin's part name marking for one device. GOWIN devices are screened using industrial standards, so the same device can be used for both industrial (I) and commercial (C) applications. The maximum temperature of the industrial grade is 100℃, and the maximum temperature of the commercial grade is 85℃. Therefore, if the chip meets speed grade 8 in commercial grade applications, its speed grade will be 7 in industrial grade applications.

Figure 4-1 Part Naming Examples – ES

GW1NS - XX X XXXXXX ES

Product Series
GW1NS

Core Supply Voltage
LV Vcc: 1.2V

Logic Density
4: 4,608 LUTs

Optional Suffix
ES Engineering Sample

Package Type
QN32   (QFN32, 0.5mm)
QN32U (QFN32U, 0.5mm)
CS36   (WLCSP36, 0.4mm)
CS36U (WLCSP36U, 0.4mm)
CS49   (WLCSP49, 0.4mm)
QN48   (QFN48, 0.4mm)
MG64   (MBGA64,0.5mm)
LQ144 (LQFP144, 0.5mm)
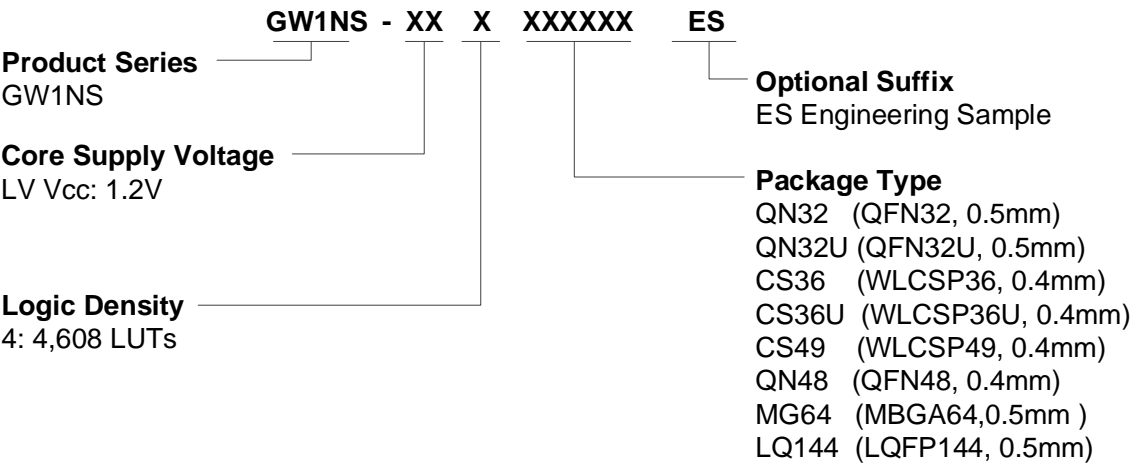
Figure 4-2 Part Naming Examples for Devices with Cortex-M3 – ES

GW1NS - XX X C XXXXXX ES

Product Series
GW1NS

Core Supply Voltage
LV Vcc:1.2V

Logic Density
4: 4,608 LUTs

C: ARM Cortex-M3

Optional Suffix
ES Engineering Sample

Package Type
QN32   (QFN32, 0.5mm)
QN32U (QFN32U, 0.5mm)
CS36   (WLCSP36, 0.4mm)
CS49   (WLCSP49, 0.4mm)
QN48   (QFN48, 0.4mm)
MG64   (MBGA64,0.5mm)
LQ144 (LQFP144, 0.5mm)
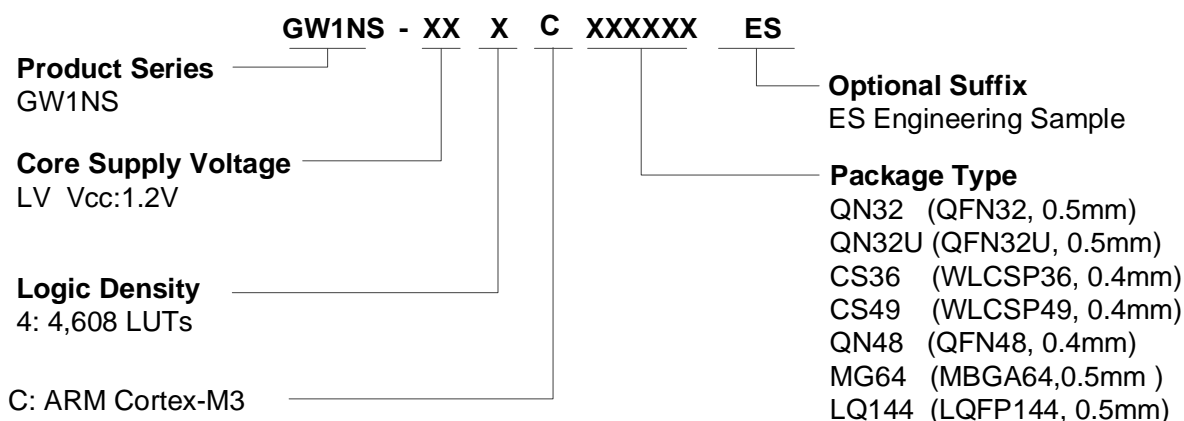
Figure 4-3 Part Naming Examples – Production

GW1NS - XX X XXXXXX CX/IX

Product Series
GW1NS

Core Supply Voltage
LV Vcc:1.2V

Logic Density
4: 4,608 LUTs

Grade
C Commercial
I Industrial
Speed
4 Slowest /5 /6 /7 Fastest

Package Type
QN32   (QFN32, 0.5mm)
QN32U (QFN32U, 0.5mm)
CS36   (WLCSP36, 0.4mm)
CS36U (WLCSP36U, 0.4mm)
CS49   (WLCSP49, 0.4mm)
QN48   (QFN48, 0.4mm)
MG64   (MBGA64,0.5mm)
LQ144 (LQFP144, 0.5mm)
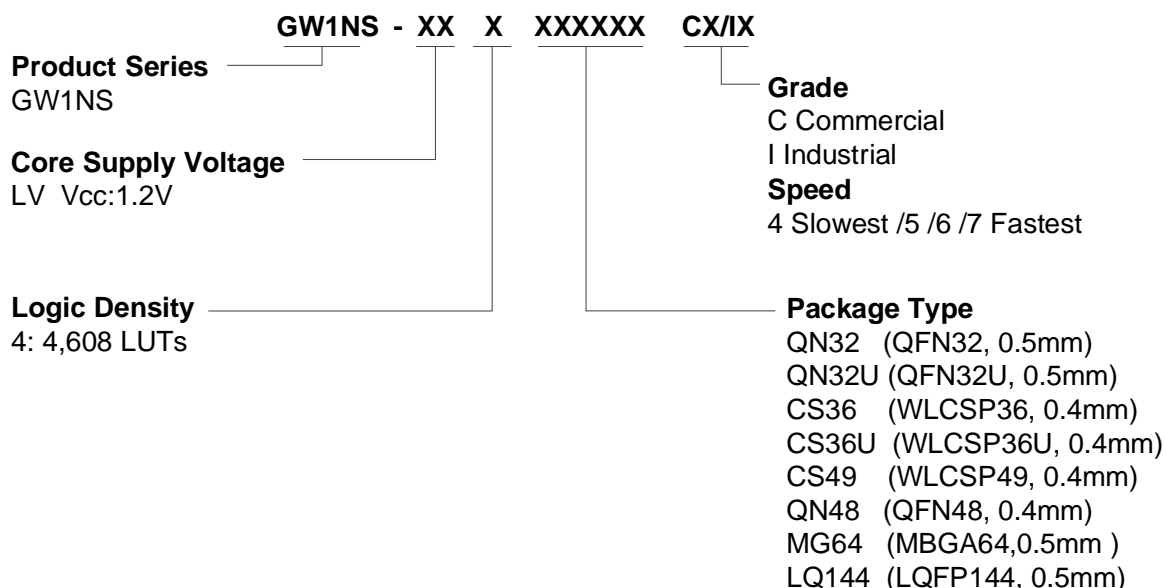
Figure 4-4 Part Naming Examples for Devices with Cortex-M3 - Production

GW1NS - XX X C XXXXXX CX/IX

Product Series
GW1NS

Core Supply Voltage
LV Vcc:1.2V

Logic Density
4: 4,608 LUTs

C: ARM Cortex-M3

Grade
C Commercial
I Industrial
Speed
4 Slowest /5 /6 /7 Fastest
Package Type
QN32   (QFN32, 0.5mm)
QN32U (QFN32U, 0.5mm)
CS36   (WLCSP36, 0.4mm)
CS49   (WLCSP49, 0.4mm)
QN48   (QFN48, 0.4mm)
MG64   (MBGA64,0.5mm)
LQ144 (LQFP144, 0.5mm)
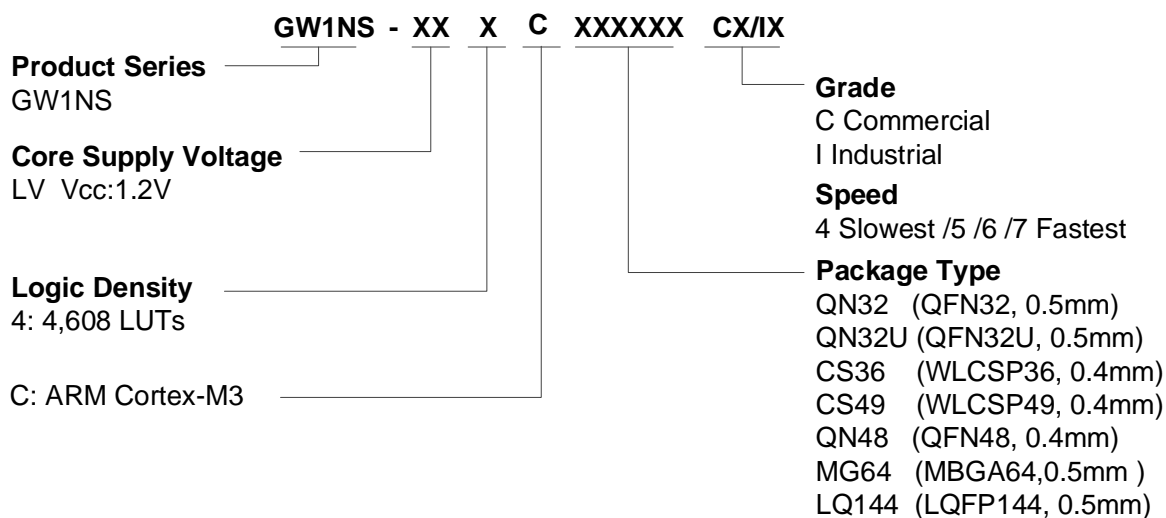
4.2 Package Markings

Gowin's devices have markings on the their surfaces, as shown in Figure 4-5.

Figure 4-5 Package Marking Examples
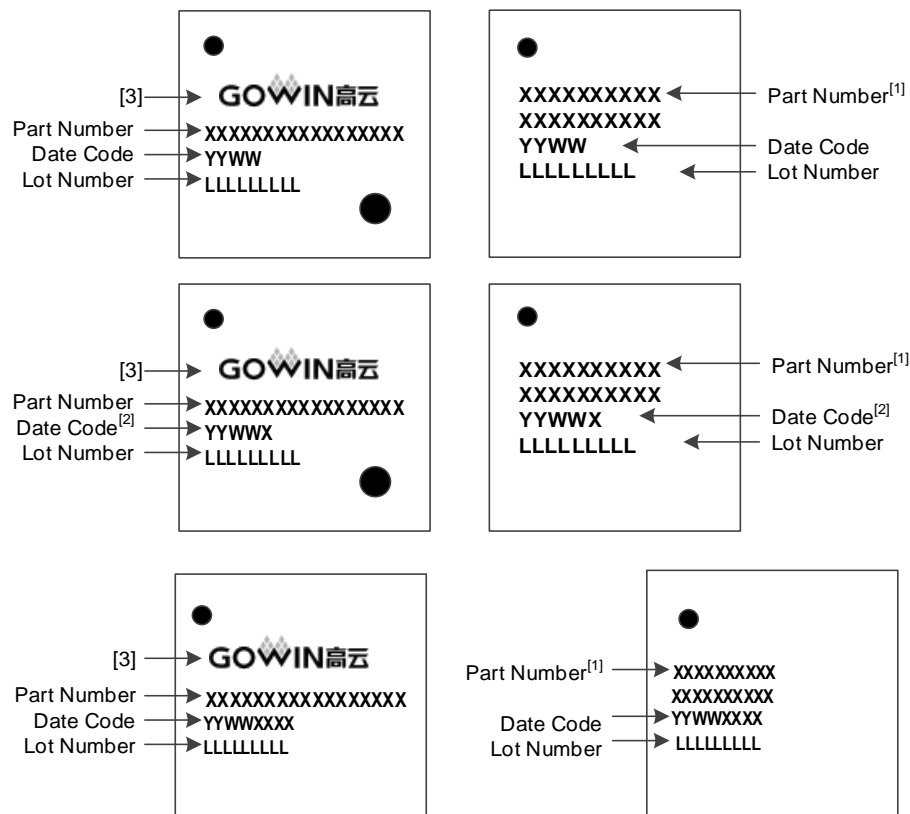
Note!

- [1] The first two lines in the right figure(s) above are both the "Part Number".

- [2] The Date Code followed by an "X" is for X version devices.

- [3] Whether the package marking bears the Gowin Logo or not depends on the package type, package size, and Part Number length. The above figure are only examples of the package markings.

5 About This Guide

5.1 Purpose

This datasheet provides a comprehensive overview of the GW1NS series of FPGA products, including their features, resources, architecture, AC/DC characteristics, and ordering details. It aims to enhance accessibility and facilitate the effective utilization of Gowin's devices.

5.2 Related Documents

The latest documents are available at www.gowinsemi.com.

- UG290, Gowin FPGA Products Programming and Configuration Guide
- UG823, GW1NS series of FPGA Products Package & Pinout User Guide
- UG824, GW1NS-4&4C Pinout

5.3 Terminology and Abbreviations

The terminology and abbreviations used in this manual are shown in Table 5-1.

Table 5-1 Terminology and Abbreviations

Terminology and Abbreviations	Full Name
AHB	Advanced High performance Bus
ALU	Arithmetic Logic Unit
APB	Advanced Peripheral Bus
ARM	Advanced RISC Machine
BSRAM	Block Static Random Access Memory
CFU	Configurable Function Unit
CLS	Configurable Logic Section
CRU	Configurable Routing Unit
CS	WLCSP
DAP	Debug Access Port
DCS	Dynamic Clock Selector
DNL	Differential Nonlinearity
DP	True Dual Port 16K BSRAM
DQCE	Dynamic Quadrant Clock Enable
DWT	Data Watchpoint Trace
FPGA	Field Programmable Gate Array
GPIO	Gowin Programmable I/O
INL	Integral Nonlinearity
IOB	Input/Output Block
ITM	Instrumentation Trace Module
LQ	LQFP
LSB	Least Significant Bit
LUT4	4-input Look-up Table
LUT5	5-input Look-up Table
LUT6	6-input Look-up Table
LUT7	7-input Look-up Table
LUT8	8-input Look-up Table
MG	MBGA
NVIC	Nested Vector Interrupt Controller
PG	PBGA
PHY	Physical Layer
PLL	Phase-locked Loop
QN	QFN

Terminology and Abbreviations	Full Name
REG	Register
SAR	Successive Approximation Register
SDP	Semi Dual Port 16K BSRAM
SFDR	Spurious-freeDynamic Range
SINAD	Signal to Noise And Distortion
SoC	System on Chip
SP	Single Port 16K BSRAM
SSRAM	Shadow Static Random Access Memory
TDM	Time Division Multiplexing
Timer	Timer
TimeStamp	TimeStamp
TUIP	Trace Port Interface Unit
UART	Universal Asynchronous Receiver/Transmitter
UG	UBGA
USB	Universal Serial Bus
Watchdog	Watchdog

5.4 Support and Feedback

Gowin Semiconductor provides customers with comprehensive technical support. If you have any questions, comments, or suggestions, please feel free to contact us directly using the information provided below.

Website:www.gowinsemi.com

E-mail:support@gowinsemi.com